

# ISO773x High-Speed, Robust-EMC Reinforced and Basic Triple-Channel Digital Isolators

## 1 Features

- 100Mbps data rate
- Robust isolation barrier:
  - >30-year projected lifetime at 1500V<sub>RMS</sub> working voltage
  - Up to 5000V<sub>RMS</sub> isolation rating
  - Up to 12.8kV surge capability
  - ±100kV/μs typical CMTI
- Wide supply range: 2.25V to 5.5V
- 2.25V to 5.5V Level translation
- Default output *high* (ISO773x) and *low* (ISO773xF) options
- Wide temperature range: –55°C to +125°C
- Low power consumption, typical 1.5mA per channel at 1Mbps
- Low propagation delay: 11ns Typical (5V Supplies)
- Robust electromagnetic compatibility (EMC)
  - System-level ESD, EFT, and surge immunity
  - ±8 kV IEC 61000-4-2 contact discharge protection across isolation barrier
  - Low emissions
- Wide-SOIC (DW-16) and QSOP (DBQ-16) package options
- Automotive version available: [ISO773x-Q1](#)
- **Safety-Related Certifications:**
  - DIN EN IEC 60747-17 (VDE 0884-17)
  - UL 1577 component recognition program
  - IEC 61010-1, IEC 62368-1, IEC60601-1, and GB 4943.1 certifications

## 2 Applications

- [Industrial automation](#)
- [Motor control](#)
- [Power supplies](#)
- [Solar inverters](#)
- [Medical equipment](#)

## 3 Description

The ISO773x devices are high-performance, triple-channel digital isolators with 5000V<sub>RMS</sub> (DW package) and 3000V<sub>RMS</sub> (DBQ package) isolation ratings per UL 1577.

This family includes devices with reinforced insulation ratings according to VDE, CSA, TUV and CQC. The ISO7731B device is designed for applications that require basic insulation ratings only.

The ISO773x family of devices provides high electromagnetic immunity and low emissions at

low power consumption, while isolating CMOS or LVCMOS digital I/Os. Each isolation channel has a logic input and output buffer separated by a double capacitive silicon dioxide (SiO<sub>2</sub>) insulation barrier. This device comes with enable pins which can be used to put the respective outputs in high impedance for multi-controller driving applications and to reduce power consumption.

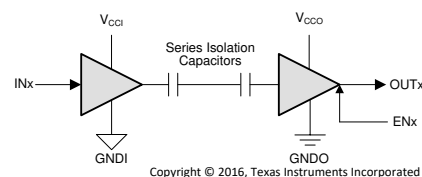
The ISO7730 device has all three channels in the same direction and the ISO7731 device has two forward and one reverse-direction channel. If the input power or signal is lost, the default output is *high* for devices without suffix F and *low* for devices with suffix F. See the [Device Functional Modes](#) section for further details.

Used in conjunction with isolated power supplies, this family of devices helps prevent noise currents on data buses, such as RS-485, RS-232, and CAN, or other circuits from entering the local ground and interfering with or damaging sensitive circuitry. Through innovative chip design and layout techniques, electromagnetic compatibility of the ISO773x device has been significantly enhanced to ease system-level ESD, EFT, surge, and emissions compliance. The ISO773x family of devices is available in 16-pin wide-SOIC and QSOP packages.

### Package Information

| PART NUMBER | PACKAGE <sup>(1)</sup> | PACKAGE SIZE <sup>(2)</sup> |
|-------------|------------------------|-----------------------------|
| ISO7730     | SOIC (DW)              | 10.30mm × 7.50mm            |
| ISO7731     | SSOP (DBQ)             | 4.90mm × 3.90mm             |
| ISO7731B    | SOIC (DW)              | 10.30mm × 7.50mm            |

- (1) For all available packages, see the orderable addendum at the end of the data sheet.
- (2) The package size (length × width) is a nominal value and includes pins, where applicable.



V<sub>CCI</sub>=Input supply, V<sub>CCO</sub>=Output supply  
GNDI=Input ground, GNDO=Output ground

### Simplified Schematic

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## 4 Pin Configuration and Functions

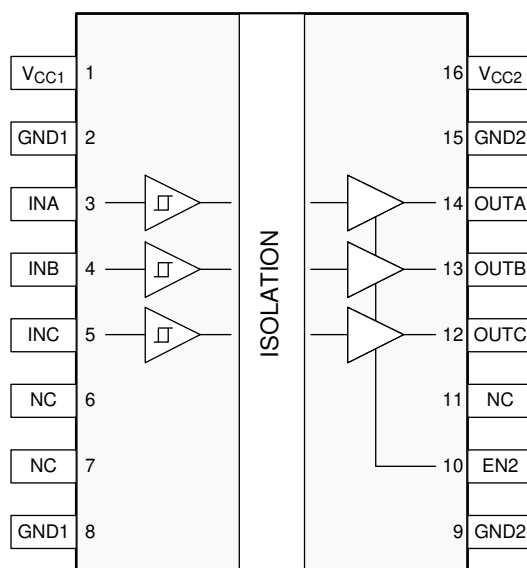
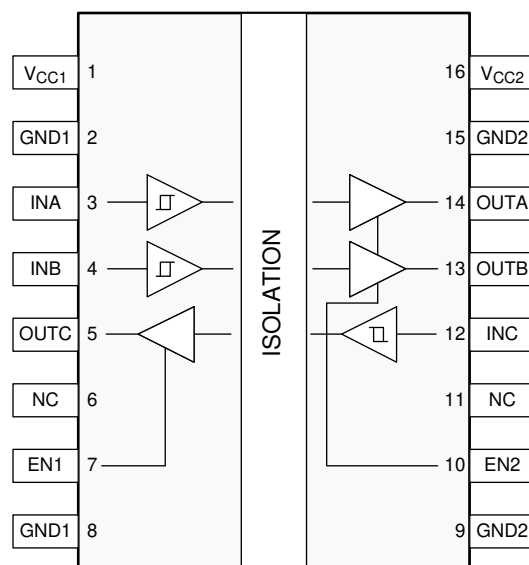


Figure 4-1. ISO7730 DW and DBQ Packages 16-Pin SOIC-WB and QSOP Top View



**Figure 4-2. ISO7731 DW and DBQ Packages 16-Pin SOIC-WB and QSOP Top View**

**Table 4-1. Pin Functions**

| PIN              |          |         | Type <sup>(1)</sup> | DESCRIPTION  |
|------------------|----------|---------|---------------------|--|
| NAME             | NO.      |         |                     |  |
|                  | ISO7730  | ISO7731 |                     |  |
| EN1              | —        | 7       | I                   | Output enable 1. Output pins on side 1 are enabled when EN1 is high or open and in high-impedance state when EN1 is low. |
| EN2              | 10       | 10      | I                   | Output enable 2. Output pins on side 2 are enabled when EN2 is high or open and in high-impedance state when EN2 is low. |
| GND1             | 2, 8     | 2, 8    | —                   | Ground connection for V <sub>CC1</sub>   |
| GND2             | 9, 15    | 9, 15   | —                   | Ground connection for V <sub>CC2</sub>   |
| INA              | 3        | 3       | I                   | Input, channel A   |
| INB              | 4        | 4       | I                   | Input, channel B   |
| INC              | 5        | 12      | I                   | Input, channel C   |
| NC               | 6, 7, 11 | 6, 11   | —                   | Not connected  |
| OUTA             | 14       | 14      | O                   | Output, channel A  |
| OUTB             | 13       | 13      | O                   | Output, channel B  |
| OUTC             | 12       | 5       | O                   | Output, channel C  |
| V <sub>CC1</sub> | 1        | 1       | —                   | Power supply, V <sub>CC1</sub>   |
| V <sub>CC2</sub> | 16       | 16      | —                   | Power supply, V <sub>CC2</sub>   |

## 5 Specifications

### 5.1 Absolute Maximum Ratings

See<sup>(1)</sup>

|                    |                               | MIN  | MAX                            | UNIT |
|--------------------|-------------------------------|------|--------------------------------|------|
| $V_{CC1}, V_{CC2}$ | Supply voltage <sup>(2)</sup> | -0.5 | 6                              | V    |
| V                  | Voltage at INx, OUTx, ENx     | -0.5 | $V_{CCX} + 0.5$ <sup>(3)</sup> | V    |
| $I_O$              | Output current                | -15  | 15                             | mA   |
| $T_J$              | Junction temperature          |      | 150                            | °C   |
| $T_{stg}$          | Storage temperature           | -65  | 150                            | °C   |

- (1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) All voltage values except differential I/O bus voltages are with respect to the local ground terminal (GND1 or GND2) and are peak voltage values
- (3) Maximum voltage must not exceed 6 V.

### 5.2 ESD Ratings

|             |                         |  | VALUE | UNIT |
|-------------|-------------------------|--|-------|------|
| $V_{(ESD)}$ | Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup>              | ±6000 | V    |
|             |                         | Charged device model (CDM), per JEDEC specification JESD22-C101, all pins <sup>(2)</sup> | ±1500 |      |
|             |                         | Contact discharge per IEC 61000-4-2; Isolation barrier withstand test <sup>(3) (4)</sup> | ±8000 |      |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.
- (3) IEC ESD strike is applied across the barrier with all pins on each side tied together creating a two-terminal device.
- (4) Testing is carried out in air or oil to determine the intrinsic contact discharge capability of the device.

### 5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

|                    |   |                              | MIN                        | NOM                  | MAX       | UNIT |
|--------------------|---|------------------------------|----------------------------|----------------------|-----------|------|
| $V_{CC1}, V_{CC2}$ | Supply voltage                                |                              | 2.25                       |                      | 5.5       | V    |
| $V_{CC(UVLO+)}$    | UVLO threshold when supply voltage is rising  |                              |                            | 2                    | 2.25      | V    |
| $V_{CC(UVLO-)}$    | UVLO threshold when supply voltage is falling |                              | 1.7                        | 1.8                  |           | V    |
| $V_{HYS(UVLO)}$    | Supply voltage UVLO hysteresis                |                              | 100                        | 200                  |           | mV   |
| $I_{OH}$           | High level output current                     | $V_{CCO}^{(1)} = 5\text{ V}$ | -4                         |                      |           | mA   |
|                    |   | $V_{CCO} = 3.3\text{ V}$     | -2                         |                      |           |      |
|                    |   | $V_{CCO} = 2.5\text{ V}$     | -1                         |                      |           |      |
| $I_{OL}$           | Low level output current                      | $V_{CCO} = 5\text{ V}$       |                            |                      | 4         | mA   |
|                    |   | $V_{CCO} = 3.3\text{ V}$     |                            |                      | 2         |      |
|                    |   | $V_{CCO} = 2.5\text{ V}$     |                            |                      | 1         |      |
| $V_{IH}$           | High-level input voltage                      |                              | $0.7 \times V_{CCI}^{(1)}$ |                      | $V_{CCI}$ | V    |
| $V_{IL}$           | Low-level input voltage                       |                              | 0                          | $0.3 \times V_{CCI}$ |           | V    |
| DR <sup>(2)</sup>  | Data rate                                     |                              | 0                          |                      | 100       | Mbps |
| $T_A$              | Ambient temperature                           |                              | -55                        | 25                   | 125       | °C   |

(1)  $V_{CCI}$  = Input-side  $V_{CC}$ ;  $V_{CCO}$  = Output-side  $V_{CC}$

(2) 100 Mbps is the maximum specified data rate, although higher data rates are possible.

## 5.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |  | ISO773x   |            | UNIT |
|-------------------------------|--|-----------|------------|------|
|                               |  | DW (SOIC) | DBQ (QSOP) |      |
|                               |  | 16 PINS   | 16 PINS    |      |
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance       | 81.4      | 109        | °C/W |
| R <sub>θJC(top)</sub>         | Junction-to-case (top) thermal resistance    | 44.9      | 46.8       | °C/W |
| R <sub>θJB</sub>              | Junction-to-board thermal resistance         | 45.9      | 60.6       | °C/W |
| Ψ <sub>JT</sub>               | Junction-to-top characterization parameter   | 28.1      | 35.9       | °C/W |
| Ψ <sub>JB</sub>               | Junction-to-board characterization parameter | 45.5      | 60         | °C/W |
| R <sub>θJC(bot)</sub>         | Junction-to-case (bottom) thermal resistance | -         | -          | °C/W |

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application note.

## 5.5 Power Ratings

| PARAMETER       |  | TEST CONDITIONS  | MIN | TYP | MAX | UNIT |
|-----------------|--|--|-----|-----|-----|------|
| ISO7730         |  |  |     |     |     |      |
| P <sub>D</sub>  | Maximum power dissipation (both sides) | V <sub>CC1</sub> = V <sub>CC2</sub> = 5.5 V, T <sub>J</sub> = 150°C, C <sub>L</sub> = 15 pF, input a 50-MHz 50% duty cycle square wave |     |     | 160 | mW   |
| P <sub>D1</sub> | Maximum power dissipation (side-1)     |  |     |     | 30  | mW   |
| P <sub>D2</sub> | Maximum power dissipation (side-2)     |  |     |     | 130 | mW   |
| ISO7731         |  |  |     |     |     |      |
| P <sub>D</sub>  | Maximum power dissipation (both sides) | V <sub>CC1</sub> = V <sub>CC2</sub> = 5.5 V, T <sub>J</sub> = 150°C, C <sub>L</sub> = 15 pF, input a 50-MHz 50% duty cycle square wave |     |     | 160 | mW   |
| P <sub>D1</sub> | Maximum power dissipation (side-1)     |  |     |     | 60  | mW   |
| P <sub>D2</sub> | Maximum power dissipation (side-2)     |  |     |     | 100 | mW   |

## 5.6 Insulation Specifications

| PARAMETER  |   | TEST CONDITIONS  | VALUE  |        | UNIT  |                  |
|--|---|--|--|--------|-------|------------------|
|  |   |  | DW-16  | DBQ-16 |       |                  |
| CLR  | External clearance <sup>(1)</sup>                   | Shortest terminal-to-terminal distance through air   |  | >8     | >3.7  | mm               |
| CPG  | External creepage <sup>(1)</sup>                    | Shortest terminal-to-terminal distance across the package surface  |  | >8     | >3.7  | mm               |
| DTI  | Distance through the insulation                     | Minimum internal gap (internal clearance)  |  | >17    | >17   | µm               |
| CTI  | Comparative tracking index                          | DIN EN 60112 (VDE 0303-11); IEC 60112, UL 746A   |  | >600   | >600  | V                |
|  | Material group                                      | According to IEC 60664-1   |  | I      | I     |                  |
|  | Overvoltage category per IEC 60664-1                | Rated mains voltage ≤ 150 V <sub>RMS</sub>   |  | I-IV   | I-IV  |                  |
|  |   | Rated mains voltage ≤ 300 V <sub>RMS</sub>   |  | I-IV   | I-III |                  |
|  |   | Rated mains voltage ≤ 600 V <sub>RMS</sub>   |  | I-IV   | n/a   |                  |
|  |   | Rated mains voltage ≤ 1000 V <sub>RMS</sub>  |  | I-III  | n/a   |                  |
| DIN EN IEC 60747-17 (VDE 0884-17) <sup>(2)</sup> |   |  |  |        |       |                  |
| V <sub>IORM</sub>                                | Maximum repetitive peak isolation voltage           | AC voltage (bipolar)   | ISO773x  | 2121   | 566   | V <sub>PK</sub>  |
| V <sub>IORM</sub>                                | Maximum repetitive peak isolation voltage           | AC voltage (bipolar)   | ISO7731B   | 1414   | n/a   | V <sub>PK</sub>  |
| V <sub>IOWM</sub>                                | Maximum working isolation voltage                   | AC voltage; Time dependent dielectric breakdown (TDDB) Test; See <a href="#">Section 8.2.3.1</a>   | ISO773x  | 1500   | 400   | V <sub>RMS</sub> |
| V <sub>IOWM</sub>                                | Maximum working isolation voltage                   | AC voltage; Time dependent dielectric breakdown (TDDB) Test; See <a href="#">Section 8.2.3.1</a>   | ISO7731B   | 1000   | n/a   | V <sub>RMS</sub> |
| V <sub>IOWM</sub>                                | Maximum working isolation voltage                   | DC voltage   | ISO773x  | 2121   | 566   | V <sub>DC</sub>  |
| V <sub>IOWM</sub>                                | Maximum working isolation voltage                   | DC voltage   | ISO7731B   | 1414   | n/a   | V <sub>DC</sub>  |
| V <sub>IOTM</sub>                                | Maximum transient isolation voltage                 | V <sub>TEST</sub> = V <sub>IOTM</sub> , t = 60 s (qualification);<br>V <sub>TEST</sub> = 1.2 x V <sub>IOTM</sub> , t = 1 s (100% production)   |  | 8000   | 4242  | V <sub>PK</sub>  |
| V <sub>IMP</sub>                                 | Maximum impulse voltage <sup>(3)</sup>              | Tested in air, 1.2/50-µs waveform per IEC 62368-1  | ISO773x  | 8000   | 5000  | V <sub>PK</sub>  |
| V <sub>IMP</sub>                                 | Maximum impulse voltage <sup>(3)</sup>              | Tested in air, 1.2/50-µs waveform per IEC 62368-1  | ISO7731B   | 6000   | n/a   | V <sub>PK</sub>  |
| V <sub>IOSM</sub>                                | Maximum surge isolation voltage <sup>(4)</sup>      | V <sub>IOSM</sub> ≥ 1.3 x V <sub>IMP</sub> ; Tested in oil (qualification test),<br>1.2/50-µs waveform per IEC 62368-1   | ISO773x  | 12800  | 10000 | V <sub>PK</sub>  |
| V <sub>IOSM</sub>                                | Maximum surge isolation voltage <sup>(4)</sup>      | V <sub>IOSM</sub> ≥ 1.3 x V <sub>IMP</sub> ; Tested in oil (qualification test),<br>1.2/50-µs waveform per IEC 62368-1   | ISO7731B   | 7800   | n/a   | V <sub>PK</sub>  |
| q <sub>pd</sub>                                  | Apparent charge <sup>(5)</sup>                      | Method a, After Input/Output safety test subgroup 2/3,<br>V <sub>ini</sub> = V <sub>IOTM</sub> , t <sub>ini</sub> = 60 s;<br>V <sub>pd(m)</sub> = 1.2 x V <sub>IORM</sub> , t <sub>m</sub> = 10 s  |  | ≤5     | ≤5    | pC               |
| q <sub>pd</sub>                                  | Apparent charge <sup>(5)</sup>                      | Method a, After environmental tests subgroup 1,<br>V <sub>ini</sub> = V <sub>IOTM</sub> , t <sub>ini</sub> = 60 s;   | V <sub>pd(m)</sub> = 1.6 x V <sub>IORM</sub> ,<br>t <sub>m</sub> = 10 s (ISO773x)  | ≤5     | ≤5    | pC               |
| q <sub>pd</sub>                                  | Apparent charge <sup>(5)</sup>                      | Method a, After environmental tests subgroup 1,<br>V <sub>ini</sub> = V <sub>IOTM</sub> , t <sub>ini</sub> = 60 s;   | V <sub>pd(m)</sub> = 1.3 x V <sub>IORM</sub> ,<br>t <sub>m</sub> = 10 s (ISO7731B) | ≤5     | n/a   | pC               |
| q <sub>pd</sub>                                  | Apparent charge <sup>(5)</sup>                      | Method b; At routine test (100% production) and preconditioning (type test);<br>V <sub>ini</sub> = 1.2 x V <sub>IOTM</sub> , t <sub>ini</sub> = 1 s;<br>V <sub>pd(m)</sub> = 1.875 x V <sub>IORM</sub> (ISO773x) or<br>V <sub>pd(m)</sub> = 1.5 x V <sub>IORM</sub> (ISO7731B), t <sub>m</sub> = 1 s (method b1) or<br>V <sub>pd(m)</sub> = V <sub>ini</sub> , t <sub>m</sub> = t <sub>ini</sub> (method b2) |  | ≤5     | ≤5    | pC               |
| C <sub>IO</sub>                                  | Barrier capacitance, input to output <sup>(6)</sup> | V <sub>IO</sub> = 0.4 x sin (2πft), f = 1 MHz  |  | ≈0.7   | ≈0.7  | pF               |

| PARAMETER        |  | TEST CONDITIONS  | VALUE             |                   | UNIT             |
|------------------|--|--|-------------------|-------------------|------------------|
|                  |  |  | DW-16             | DBQ-16            |                  |
| R <sub>IO</sub>  | Isolation resistance <sup>(6)</sup>    | V <sub>IO</sub> = 500 V, T <sub>A</sub> = 25°C   | >10 <sup>12</sup> | >10 <sup>12</sup> | Ω                |
|                  |  | V <sub>IO</sub> = 500 V, 100°C ≤ T <sub>A</sub> ≤ 125°C  | >10 <sup>11</sup> | >10 <sup>11</sup> |                  |
|                  |  | V <sub>IO</sub> = 500 V at T <sub>S</sub> = 150°C  | >10 <sup>9</sup>  | >10 <sup>9</sup>  |                  |
|                  | Pollution degree                       |  | 2                 | 2                 |                  |
|                  | Climatic category                      |  | 55/125/21         | 55/125/21         |                  |
| <b>UL 1577</b>   |  |  |                   |                   |                  |
| V <sub>ISO</sub> | Maximum withstanding isolation voltage | V <sub>TEST</sub> = V <sub>ISO</sub> , t = 60 s (qualification),<br>V <sub>TEST</sub> = 1.2 x V <sub>ISO</sub> , t = 1 s (100% production) | 5000              | 3000              | V <sub>RMS</sub> |

- (1) Creepage and clearance requirements should be applied according to the specific equipment isolation standards of an application. Care should be taken to maintain the creepage and clearance distance of a board design to ensure that the mounting pads of the isolator on the printed-circuit board do not reduce this distance. Creepage and clearance on a printed-circuit board become equal in certain cases. Techniques such as inserting grooves and/or ribs on a printed-circuit board are used to help increase these specifications.
- (2) This coupler is suitable for *safe electrical insulation* (ISO773x) and basic electrical insulation (ISO7731B) only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.
- (3) Testing is carried out in air to determine the surge immunity of the package
- (4) Testing is carried out in oil to determine the intrinsic surge immunity of the isolation barrier.
- (5) Apparent charge is electrical discharge caused by a partial discharge (pd).
- (6) All pins on each side of the barrier tied together creating a two-terminal device.



## 5.7 Safety-Related Certifications

| VDE  | CSA   | UL  | CQC   | TUV  |
|--|---|---|---|--|
| Certified according to DIN EN IEC 60747-17 (VDE 0884-17)   | Certified according to IEC 62368-1 and IEC 60601  | Certified according to UL 1577 Component Recognition Program  | Certified according to GB4943.1   | Certified according to EN 61010-1 and EN 62368-1   |
| Maximum transient isolation voltage, 8000 V <sub>PK</sub> (DW-16) and 4242 V <sub>PK</sub> (DBQ-16);<br>Maximum repetitive peak isolation voltage, 2121 V <sub>PK</sub> (DW-16, Reinforced), 1414 V <sub>PK</sub> (DW-16, Basic) and 566 V <sub>PK</sub> (DBQ-16);<br>Maximum surge isolation voltage, 12800 V <sub>PK</sub> (DW-16, Reinforced), 7800 V <sub>PK</sub> (DW-16, Basic) and 10000 V <sub>PK</sub> (DBQ-16) | Reinforced insulation per CSA 62368-1 and IEC 62368-1, 600 V <sub>RMS</sub> (DW-16) and 370 V <sub>RMS</sub> (DBQ-16) max working voltage (pollution degree 2, material group I);<br>2 MOPP (Means of Patient Protection) per CSA 60601-1 and IEC 60601-1, 250 V <sub>RMS</sub> (DW-16) max working voltage | DW-16: Single protection, 5000 V <sub>RMS</sub> ;<br>DBQ-16: Single protection, 3000 V <sub>RMS</sub> | DW-16: Reinforced Insulation, Altitude ≤ 5000 m, Tropical Climate, 700 V <sub>RMS</sub> maximum working voltage;<br>DBQ-16: Basic Insulation, Altitude ≤ 5000 m, Tropical Climate, 400 V <sub>RMS</sub> maximum working voltage | 5000 V <sub>RMS</sub> (DW-16) and 3000 V <sub>RMS</sub> (DBQ-16)<br>Reinforced insulation per EN 61010-1 up to working voltage of 600 V <sub>RMS</sub> (DW-16) and 300 V <sub>RMS</sub> (DBQ-16)<br>5000 V <sub>RMS</sub> (DW-16) and 3000 V <sub>RMS</sub> (DBQ-16)<br>Reinforced insulation per EN 62368-1 up to working voltage of 600 V <sub>RMS</sub> (DW-16) and 370 V <sub>RMS</sub> (DBQ-16) of 600 V <sub>RMS</sub> |
| Certificate numbers:<br>40040142 (Reinforced)<br>40047657 (Basic)  | Master contract number:<br>220991   | File number: E181974  | Certificate numbers:<br>CQC21001304083 (DW-16)<br>CQC18001199097 (DBQ-16)   | Client ID number: 077311   |

## 5.8 Safety Limiting Values

Safety limiting<sup>(1)</sup> intends to minimize potential damage to the isolation barrier upon failure of input or output circuitry. A failure of the I/O can allow low resistance to ground or the supply and, without current limiting, dissipate sufficient power to overheat the die and damage the isolation barrier potentially leading to secondary system failures.

| PARAMETER             |  | TEST CONDITIONS   | MIN | TYP | MAX  | UNIT               |
|-----------------------|--|---|-----|-----|------|--------------------|
| <b>DW-16 PACKAGE</b>  |  |   |     |     |      |                    |
| $I_S$                 | Safety input, output, or supply current. | $R_{\theta JA} = 81.4^{\circ}\text{C/W}$ , $V_I = 5.5\text{ V}$ , $T_J = 150^{\circ}\text{C}$ , $T_A = 25^{\circ}\text{C}$ , see <a href="#">Figure 5-1</a>   |     |     | 279  | mA                 |
|                       |  | $R_{\theta JA} = 81.4^{\circ}\text{C/W}$ , $V_I = 3.6\text{ V}$ , $T_J = 150^{\circ}\text{C}$ , $T_A = 25^{\circ}\text{C}$ , see <a href="#">Figure 5-1</a>   |     |     | 427  |                    |
|                       |  | $R_{\theta JA} = 81.4^{\circ}\text{C/W}$ , $V_I = 2.75\text{ V}$ , $T_J = 150^{\circ}\text{C}$ , $T_A = 25^{\circ}\text{C}$ , see <a href="#">Figure 5-1</a>  |     |     | 558  |                    |
| $P_S$                 | Safety input, output, or total power     | $R_{\theta JA} = 81.4^{\circ}\text{C/W}$ , $T_J = 150^{\circ}\text{C}$ , $T_A = 25^{\circ}\text{C}$ , see <a href="#">Figure 5-3</a>                          |     |     | 1536 | mW                 |
| $T_S$                 | Maximum safety temperature               |   |     |     | 150  | $^{\circ}\text{C}$ |
| <b>DBQ-16 PACKAGE</b> |  |   |     |     |      |                    |
| $I_S$                 | Safety input, output, or supply current  | $R_{\theta JA} = 109.0^{\circ}\text{C/W}$ , $V_I = 5.5\text{ V}$ , $T_J = 150^{\circ}\text{C}$ , $T_A = 25^{\circ}\text{C}$ , see <a href="#">Figure 5-2</a>  |     |     | 209  | mA                 |
|                       |  | $R_{\theta JA} = 109.0^{\circ}\text{C/W}$ , $V_I = 3.6\text{ V}$ , $T_J = 150^{\circ}\text{C}$ , $T_A = 25^{\circ}\text{C}$ , see <a href="#">Figure 5-2</a>  |     |     | 319  |                    |
|                       |  | $R_{\theta JA} = 109.0^{\circ}\text{C/W}$ , $V_I = 2.75\text{ V}$ , $T_J = 150^{\circ}\text{C}$ , $T_A = 25^{\circ}\text{C}$ , see <a href="#">Figure 5-2</a> |     |     | 417  |                    |
| $P_S$                 | Safety input, output, or total power     | $R_{\theta JA} = 109.0^{\circ}\text{C/W}$ , $T_J = 150^{\circ}\text{C}$ , $T_A = 25^{\circ}\text{C}$ , see <a href="#">Figure 5-4</a>                         |     |     | 1147 | mW                 |
| $T_S$                 | Maximum safety temperature               |   |     |     | 150  | $^{\circ}\text{C}$ |

- (1) The maximum safety temperature,  $T_S$ , has the same value as the maximum junction temperature,  $T_J$ , specified for the device. The  $I_S$  and  $P_S$  parameters represent the safety current and safety power respectively. The maximum limits of  $I_S$  and  $P_S$  should not be exceeded. These limits vary with the ambient temperature,  $T_A$ .  
The junction-to-air thermal resistance,  $R_{\theta JA}$ , in the table is that of a device installed on a high-K test board for leaded surface-mount packages. Use these equations to calculate the value for each parameter:  
 $T_J = T_A + R_{\theta JA} \times P$ , where  $P$  is the power dissipated in the device.  
 $T_{J(max)} = T_S = T_A + R_{\theta JA} \times P_S$ , where  $T_{J(max)}$  is the maximum allowed junction temperature.  
 $P_S = I_S \times V_I$ , where  $V_I$  is the maximum input voltage.

## 5.9 Electrical Characteristics—5-V Supply

$V_{CC1} = V_{CC2} = 5\text{ V} \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER     |                                    | TEST CONDITIONS   | MIN                            | TYP                  | MAX                  | UNIT                    |
|---------------|------------------------------------|---|--------------------------------|----------------------|----------------------|-------------------------|
| $V_{OH}$      | High-level output voltage          | $I_{OH} = -4\text{ mA}$ ; See <a href="#">Figure 6-1</a>                                    | $V_{CCO} - 0.4$ <sup>(1)</sup> | 4.8                  |                      | V                       |
| $V_{OL}$      | Low-level output voltage           | $I_{OL} = 4\text{ mA}$ ; See <a href="#">Figure 6-1</a>                                     |                                | 0.2                  | 0.4                  | V                       |
| $V_{IT+(IN)}$ | Rising input switching threshold   |   |                                | $0.6 \times V_{CCI}$ | $0.7 \times V_{CCI}$ | V                       |
| $V_{IT-(IN)}$ | Falling input switching threshold  |   | $0.3 \times V_{CCI}$           | $0.4 \times V_{CCI}$ |                      | V                       |
| $V_{I(HYS)}$  | Input threshold voltage hysteresis |   | $0.1 \times V_{CCI}$           | $0.2 \times V_{CCI}$ |                      | V                       |
| $I_{IH}$      | High-level input current           | $V_{IH} = V_{CCI}$ <sup>(1)</sup> at INx  |                                |                      | 10                   | $\mu\text{A}$           |
| $I_{IL}$      | Low-level input current            | $V_{IL} = 0\text{ V}$ at INx  | -10                            |                      |                      | $\mu\text{A}$           |
| $I_{IH}$      | High-level input current           | $V_{IH} = V_{CCI}$ <sup>(1)</sup> at ENx  |                                |                      | 28                   | $\mu\text{A}$           |
| $I_{IL}$      | Low-level input current            | $V_{IL} = 0\text{ V}$ at ENx  | -28                            |                      |                      | $\mu\text{A}$           |
| CMTI          | Common mode transient immunity     | $V_I = V_{CCI}$ or $0\text{ V}$ , $V_{CM} = 1200\text{ V}$ ; See <a href="#">Figure 6-4</a> | 85                             | 100                  |                      | $\text{kV}/\mu\text{s}$ |
| $C_i$         | Input capacitance <sup>(2)</sup>   | $V_I = V_{CC}/2 + 0.4 \times \sin(2\pi ft)$ , $f = 1\text{ MHz}$ , $V_{CC} = 5\text{ V}$    |                                | 2                    |                      | pF                      |

(1)  $V_{CCI}$  = Input-side  $V_{CC}$ ;  $V_{CCO}$  = Output-side  $V_{CC}$

(2) Measured from input pin to same side ground.

## 5.10 Supply Current Characteristics—5-V Supply

 $V_{CC1} = V_{CC2} = 5\text{ V} \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER                  | TEST CONDITIONS  |          | SUPPLY CURRENT   | MIN | TYP  | MAX  | UNIT |
|----------------------------|--|----------|------------------|-----|------|------|------|
| ISO7730                    |  |          |                  |     |      |      |      |
| Supply current - disable   | EN2 = 0 V; V <sub>I</sub> = V <sub>CC1</sub> (ISO7730);<br>V <sub>I</sub> = 0 V (ISO7730 with F suffix)                                    |          | I <sub>CC1</sub> |     | 1    | 2.3  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 0.3  | 0.8  | mA   |
|                            | EN2 = 0 V; V <sub>I</sub> = 0 V (ISO7730);<br>V <sub>I</sub> = V <sub>CC1</sub> (ISO7730 with F suffix)                                    |          | I <sub>CC1</sub> |     | 4.3  | 6    | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 0.3  | 0.8  | mA   |
| Supply current - DC signal | EN2 = V <sub>CC2</sub> ; V <sub>I</sub> = V <sub>CC1</sub> (ISO7730);<br>V <sub>I</sub> = 0 V (ISO7730 with F suffix)                      |          | I <sub>CC1</sub> |     | 1    | 2.3  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 1.6  | 3.7  | mA   |
|                            | EN2 = V <sub>CC2</sub> ; V <sub>I</sub> = 0 V (ISO7730);<br>V <sub>I</sub> = V <sub>CC1</sub> (ISO7730 with F suffix)                      |          | I <sub>CC1</sub> |     | 4.3  | 6    | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 1.8  | 3.9  | mA   |
| Supply current - AC signal | EN2 = V <sub>CCi</sub> ; All channels switching with square wave clock input; C <sub>L</sub> = 15 pF                                       | 1 Mbps   | I <sub>CC1</sub> |     | 2.6  | 4.1  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 1.9  | 4    | mA   |
|                            |  | 10 Mbps  | I <sub>CC1</sub> |     | 2.7  | 4.3  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 3.3  | 5.7  | mA   |
|                            |  | 100 Mbps | I <sub>CC1</sub> |     | 3.6  | 5.6  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 17.5 | 23.2 | mA   |
| ISO7731                    |  |          |                  |     |      |      |      |
| Supply current - disable   | EN1 = EN2 = 0 V; V <sub>I</sub> = V <sub>CCi</sub> <sup>(1)</sup> (ISO7731);<br>V <sub>I</sub> = 0 V (ISO7731 with F suffix)               |          | I <sub>CC1</sub> |     | 0.8  | 2.2  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 0.7  | 1.6  | mA   |
|                            | EN1 = EN2 = 0 V; V <sub>I</sub> = 0 V (ISO7731);<br>V <sub>I</sub> = V <sub>CCi</sub> (ISO7731 with F suffix)                              |          | I <sub>CC1</sub> |     | 3    | 4.6  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 1.8  | 2.8  | mA   |
| Supply current - DC signal | EN1 = EN2 = V <sub>CCi</sub> ; V <sub>I</sub> = V <sub>CCi</sub> <sup>(1)</sup> (ISO7731);<br>V <sub>I</sub> = 0 V (ISO7731 with F suffix) |          | I <sub>CC1</sub> |     | 1.3  | 2.9  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 1.6  | 3.7  | mA   |
|                            | EN1 = EN2 = V <sub>CCi</sub> ; V <sub>I</sub> = 0 V (ISO7731);<br>V <sub>I</sub> = V <sub>CCi</sub> (ISO7731 with F suffix)                |          | I <sub>CC1</sub> |     | 3.5  | 5.4  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 2.8  | 5.1  | mA   |
| Supply current - AC signal | EN1 = EN2 = V <sub>CCi</sub> ; All channels switching with square wave clock input; C <sub>L</sub> = 15 pF                                 | 1 Mbps   | I <sub>CC1</sub> |     | 2.7  | 4.2  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 2.3  | 4.6  | mA   |
|                            |  | 10 Mbps  | I <sub>CC1</sub> |     | 3    | 4.9  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 3.3  | 5.8  | mA   |
|                            |  | 100 Mbps | I <sub>CC1</sub> |     | 8.5  | 11.5 | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 13.1 | 17.8 | mA   |

(1)  $V_{CCI}$  = Input-side  $V_{CC}$

## 5.11 Electrical Characteristics—3.3-V Supply

$V_{CC1} = V_{CC2} = 3.3 \text{ V} \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER     | TEST CONDITIONS  | MIN                            | TYP                  | MAX                  | UNIT                    |
|---------------|--|--------------------------------|----------------------|----------------------|-------------------------|
| $V_{OH}$      | High-level output voltage<br>$I_{OH} = -2\text{mA}$ ; See <a href="#">Figure 6-1</a>   | $V_{CCO} - 0.3$ <sup>(1)</sup> | 3.2                  |                      | V                       |
| $V_{OL}$      | Low-level output voltage<br>$I_{OL} = 2\text{mA}$ ; See <a href="#">Figure 6-1</a>   |                                | 0.1                  | 0.3                  | V                       |
| $V_{IT+(IN)}$ | Rising input switching threshold   |                                | $0.6 \times V_{CCI}$ | $0.7 \times V_{CCI}$ | V                       |
| $V_{IT-(IN)}$ | Falling input switching threshold  | $0.3 \times V_{CCI}$           | $0.4 \times V_{CCI}$ |                      | V                       |
| $V_{I(HYS)}$  | Input threshold voltage hysteresis   | $0.1 \times V_{CCI}$           | $0.2 \times V_{CCI}$ |                      | V                       |
| $I_{IH}$      | High-level input current<br>$V_{IH} = V_{CCI}$ <sup>(1)</sup> at INx   |                                |                      | 10                   | $\mu\text{A}$           |
| $I_{IL}$      | Low-level input current<br>$V_{IL} = 0 \text{ V}$ at INx   | -10                            |                      |                      | $\mu\text{A}$           |
| $I_{IH}$      | High-level input current<br>$V_{IH} = V_{CCI}$ <sup>(1)</sup> at ENx   |                                |                      | 30                   | $\mu\text{A}$           |
| $I_{IL}$      | Low-level input current<br>$V_{IL} = 0 \text{ V}$ at ENx   | -30                            |                      |                      | $\mu\text{A}$           |
| CMTI          | Common mode transient immunity<br>$V_I = V_{CCI}$ or $0 \text{ V}$ , $V_{CM} = 1200 \text{ V}$ ;<br>See <a href="#">Figure 6-4</a> | 85                             | 100                  |                      | $\text{kV}/\mu\text{s}$ |

(1)  $V_{CCI}$  = Input-side  $V_{CC}$ ;  $V_{CCO}$  = Output-side  $V_{CC}$

## 5.12 Supply Current Characteristics—3.3-V Supply

 $V_{CC1} = V_{CC2} = 3.3\text{ V} \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER                  | TEST CONDITIONS  |          | SUPPLY CURRENT   | MIN | TYP | MAX  | UNIT |
|----------------------------|--|----------|------------------|-----|-----|------|------|
| ISO7730                    |  |          |                  |     |     |      |      |
| Supply current - disable   | EN2 = 0 V; V <sub>I</sub> = V <sub>CC1</sub> (ISO7730);<br>V <sub>I</sub> = 0 V (ISO7730 with F suffix)                      |          | I <sub>CC1</sub> |     | 1   | 2.3  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 0.3 | 0.8  | mA   |
|                            | EN2 = 0 V; V <sub>I</sub> = 0 V (ISO7730);<br>V <sub>I</sub> = V <sub>CC1</sub> (ISO7730 with F suffix)                      |          | I <sub>CC1</sub> |     | 4.3 | 5.9  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 0.3 | 0.7  | mA   |
| Supply current - DC signal | EN2 = V <sub>CC2</sub> ; V <sub>I</sub> = V <sub>CC1</sub> (ISO7730);<br>V <sub>I</sub> = 0 V (ISO7730 with F suffix)        |          | I <sub>CC1</sub> |     | 1   | 2.3  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 1.6 | 3.6  | mA   |
|                            | EN2 =V <sub>CC2</sub> ; V <sub>I</sub> = 0 V (ISO7730);<br>V <sub>I</sub> = V <sub>CC1</sub> (ISO7730 with F suffix)         |          | I <sub>CC1</sub> |     | 4.3 | 5.8  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 1.8 | 3.8  | mA   |
| Supply current - AC signal | EN2 = V <sub>CCI</sub> ; All channels switching<br>with square wave clock input; C <sub>L</sub> =<br>15 pF                   | 1 Mbps   | I <sub>CC1</sub> |     | 2.6 | 4.1  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 1.8 | 3.9  | mA   |
|                            |  | 10 Mbps  | I <sub>CC1</sub> |     | 2.7 | 4.1  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 2.8 | 5.1  | mA   |
|                            |  | 100 Mbps | I <sub>CC1</sub> |     | 3.3 | 4.9  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 13  | 17.7 | mA   |
| ISO7731                    |  |          |                  |     |     |      |      |
| Supply current - disable   | EN1 = EN2 = 0 V; V <sub>I</sub> = V <sub>CCI</sub> <sup>(1)</sup> (ISO7731);<br>V <sub>I</sub> = 0 V (ISO7731 with F suffix) |          | I <sub>CC1</sub> |     | 0.8 | 2.1  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 0.7 | 1.5  | mA   |
|                            | EN1 = EN2 = 0 V; V <sub>I</sub> = 0 V (ISO7731);<br>V <sub>I</sub> = V <sub>CCI</sub> (ISO7731 with F suffix)                |          | I <sub>CC1</sub> |     | 3   | 4.5  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 1.8 | 2.8  | mA   |
| Supply current - DC signal | EN1 = EN2 = V <sub>CCI</sub> ; V <sub>I</sub> = V <sub>CCI</sub> (ISO7731);<br>V <sub>I</sub> = 0 V (ISO7731with F suffix)   |          | I <sub>CC1</sub> |     | 1.3 | 2.8  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 1.6 | 3.7  | mA   |
|                            | EN1 = EN2 = V <sub>CCI</sub> ; V <sub>I</sub> = 0 V (ISO7731);<br>V <sub>I</sub> = V <sub>CCI</sub> (ISO7731 with F suffix)  |          | I <sub>CC1</sub> |     | 3.5 | 5.3  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 2.8 | 5    | mA   |
| Supply current - AC signal | EN1 = EN2 = V <sub>CCI</sub> ; All channels<br>switching with square wave clock<br>input; C <sub>L</sub> = 15 pF             | 1 Mbps   | I <sub>CC1</sub> |     | 2.4 | 4.1  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 2.2 | 4.5  | mA   |
|                            |  | 10 Mbps  | I <sub>CC1</sub> |     | 2.8 | 4.6  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 2.9 | 5.3  | mA   |
|                            |  | 100 Mbps | I <sub>CC1</sub> |     | 6.7 | 9.2  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 10  | 14   | mA   |

(1)  $V_{CCI}$  = Input-side  $V_{CC}$

### 5.13 Electrical Characteristics—2.5-V Supply

$V_{CC1} = V_{CC2} = 2.5 \text{ V} \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER     | TEST CONDITIONS  | MIN                            | TYP                  | MAX                                 | UNIT                    |
|---------------|--|--------------------------------|----------------------|-------------------------------------|-------------------------|
| $V_{OH}$      | High-level output voltage<br>$I_{OH} = -1\text{mA}$ ; See <a href="#">Figure 6-1</a>   | $V_{CCO} - 0.2$ <sup>(1)</sup> | 2.45                 |                                     | V                       |
| $V_{OL}$      | Low-level output voltage<br>$I_{OL} = 1\text{mA}$ ; See <a href="#">Figure 6-1</a>   |                                | 0.05                 | 0.2                                 | V                       |
| $V_{IT+(IN)}$ | Rising input switching threshold   |                                | $0.6 \times V_{CCI}$ | $0.7 \times V_{CCI}$ <sup>(1)</sup> | V                       |
| $V_{IT-(IN)}$ | Falling input switching threshold  | $0.3 \times V_{CCI}$           | $0.4 \times V_{CCI}$ |                                     | V                       |
| $V_{I(HYS)}$  | Input threshold voltage hysteresis   | $0.1 \times V_{CCI}$           | $0.2 \times V_{CCI}$ |                                     | V                       |
| $I_{IH}$      | High-level input current<br>$V_{IH} = V_{CCI}$ <sup>(1)</sup> at INx   |                                |                      | 10                                  | $\mu\text{A}$           |
| $I_{IL}$      | Low-level input current<br>$V_{IL} = 0 \text{ V}$ at INx   | -10                            |                      |                                     | $\mu\text{A}$           |
| $I_{IH}$      | High-level input current<br>$V_{IH} = V_{CCI}$ <sup>(1)</sup> at ENx   |                                |                      | 30                                  | $\mu\text{A}$           |
| $I_{IL}$      | Low-level input current<br>$V_{IL} = 0 \text{ V}$ at ENx   | -30                            |                      |                                     | $\mu\text{A}$           |
| CMTI          | Common mode transient immunity<br>$V_I = V_{CCI}$ or $0 \text{ V}$ , $V_{CM} = 1200 \text{ V}$ ;<br>See <a href="#">Figure 6-4</a> | 85                             | 100                  |                                     | $\text{kV}/\mu\text{s}$ |

(1)  $V_{CCI}$  = Input-side  $V_{CC}$ ;  $V_{CCO}$  = Output-side  $V_{CC}$

## 5.14 Supply Current Characteristics—2.5-V Supply

 $V_{CC1} = V_{CC2} = 2.5\text{ V} \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER                  | TEST CONDITIONS  |          | SUPPLY CURRENT   | MIN | TYP  | MAX  | UNIT |
|----------------------------|--|----------|------------------|-----|------|------|------|
| ISO7730                    |  |          |                  |     |      |      |      |
| Supply current - disable   | EN2 = 0 V; V <sub>I</sub> = V <sub>CC1</sub> (ISO7730);<br>V <sub>I</sub> = 0 V (ISO7730 with F suffix)                      |          | I <sub>CC1</sub> |     | 1    | 2.2  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 0.3  | 0.7  | mA   |
|                            | EN2 = 0 V; V <sub>I</sub> = 0 V (ISO7730);<br>V <sub>I</sub> = V <sub>CC1</sub> (ISO7730 with F suffix)                      |          | I <sub>CC1</sub> |     | 4.3  | 5.8  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 0.3  | 0.7  | mA   |
| Supply current - DC signal | EN2 = V <sub>CC2</sub> ; V <sub>I</sub> = V <sub>CC1</sub> (ISO7730);<br>V <sub>I</sub> = 0 V (ISO7730 with F suffix)        |          | I <sub>CC1</sub> |     | 1    | 2.2  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 1.6  | 3.6  | mA   |
|                            | EN2 =V <sub>CC2</sub> ; V <sub>I</sub> = 0 V (ISO7730);<br>V <sub>I</sub> = V <sub>CC1</sub> (ISO7730 with F suffix)         |          | I <sub>CC1</sub> |     | 4.3  | 5.8  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 1.8  | 3.8  | mA   |
| Supply current - AC signal | EN2 = V <sub>CCI</sub> ; All channels switching<br>with square wave clock input; C <sub>L</sub> =<br>15 pF                   | 1 Mbps   | I <sub>CC1</sub> |     | 2.6  | 4    | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 1.8  | 3.8  | mA   |
|                            |  | 10 Mbps  | I <sub>CC1</sub> |     | 2.6  | 4.1  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 2.5  | 4.8  | mA   |
|                            |  | 100 Mbps | I <sub>CC1</sub> |     | 3.1  | 4.7  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 10.2 | 14.3 | mA   |
| ISO7731                    |  |          |                  |     |      |      |      |
| Supply current - disable   | EN1 = EN2 = 0 V; V <sub>I</sub> = V <sub>CCI</sub> <sup>(1)</sup> (ISO7731);<br>V <sub>I</sub> = 0 V (ISO7731 with F suffix) |          | I <sub>CC1</sub> |     | 0.8  | 2.1  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 0.7  | 1.5  | mA   |
|                            | EN1 = EN2 = 0 V; V <sub>I</sub> = 0 V (ISO7731);<br>V <sub>I</sub> = V <sub>CCI</sub> (ISO7731 with F suffix)                |          | I <sub>CC1</sub> |     | 3    | 4.5  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 1.8  | 2.7  | mA   |
| Supply current - DC signal | EN1 = EN2 = V <sub>CCI</sub> ; V <sub>I</sub> = V <sub>CCI</sub> (ISO7731);<br>V <sub>I</sub> = 0 V (ISO7731 with F suffix)  |          | I <sub>CC1</sub> |     | 1.3  | 2.8  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 1.6  | 3.7  | mA   |
|                            | EN1 = EN2 = V <sub>CCI</sub> ; V <sub>I</sub> = 0 V (ISO7731);<br>V <sub>I</sub> = V <sub>CCI</sub> (ISO7731 with F suffix)  |          | I <sub>CC1</sub> |     | 3.5  | 5.3  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 2.8  | 5    | mA   |
| Supply current - AC signal | EN1 = EN2 = V <sub>CCI</sub> ; All channels<br>switching with square wave clock<br>input; C <sub>L</sub> = 15 pF             | 1 Mbps   | I <sub>CC1</sub> |     | 2.4  | 4.1  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 2.2  | 4.4  | mA   |
|                            |  | 10 Mbps  | I <sub>CC1</sub> |     | 2.7  | 4.4  | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 2.7  | 5.1  | mA   |
|                            |  | 100 Mbps | I <sub>CC1</sub> |     | 5.6  | 8    | mA   |
|                            |  |          | I <sub>CC2</sub> |     | 8    | 11.6 | mA   |

(1)  $V_{CCI}$  = Input-side  $V_{CC}$



## 5.15 Switching Characteristics—5-V Supply

$V_{CC1} = V_{CC2} = 5\text{ V} \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER             |   | TEST CONDITIONS  | MIN | TYP | MAX | UNIT |
|-----------------------|---|--|-----|-----|-----|------|
| $t_{PLH}$ , $t_{PHL}$ | Propagation delay time  | See Figure 6-1   | 6   | 11  | 17  | ns   |
| PWD                   | Pulse width distortion <sup>(1)</sup> $ t_{PHL} - t_{PLH} $                       |  |     | 0.6 | 5.9 | ns   |
| $t_{sk(o)}$           | Channel-to-channel output skew time <sup>(2)</sup>                                | Same-direction channels                                    |     |     | 4   | ns   |
| $t_{sk(pp)}$          | Part-to-part skew time <sup>(3)</sup>   |  |     |     | 4.5 | ns   |
| $t_r$                 | Output signal rise time   | See Figure 6-1   |     | 1.3 | 3.9 | ns   |
| $t_f$                 | Output signal fall time   |  |     | 1.4 | 3.9 | ns   |
| $t_{PHZ}$             | Disable propagation delay, high-to-high impedance output                          | See Figure 6-2   |     | 8   | 22  | ns   |
| $t_{PLZ}$             | Disable propagation delay, low-to-high impedance output                           |  |     | 8   | 20  | ns   |
| $t_{PZH}$             | Enable propagation delay, high impedance-to-high output for ISO773x               |  |     | 7   | 20  | ns   |
|                       | Enable propagation delay, high impedance-to-high output for ISO773x with F suffix |  |     | 3   | 8.5 | μs   |
| $t_{PZL}$             | Enable propagation delay, high impedance-to-low output for ISO773x                |  |     | 3   | 8.5 | μs   |
|                       | Enable propagation delay, high impedance-to-low output for ISO773x with F suffix  |  |     | 7   | 20  | ns   |
| $t_{DO}$              | Default output delay time from input power loss                                   | Measured from the time VCC goes below 1.7V. See Figure 6-3 |     | 0.1 | 0.3 | μs   |
| $t_{ie}$              | Time interval error   | $2^{16} - 1$ PRBS data at 100 Mbps                         |     | 0.6 |     | ns   |

(1) Also known as pulse skew.

(2)  $t_{sk(o)}$  is the skew between outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical loads.

(3)  $t_{sk(pp)}$  is the magnitude of the difference in propagation delay times between any terminals of different devices switching in the same direction while operating at identical supply voltages, temperature, input signals and loads.

## 5.16 Switching Characteristics—3.3-V Supply

$V_{CC1} = V_{CC2} = 3.3 \text{ V} \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER             |   | TEST CONDITIONS  | MIN | TYP | MAX  | UNIT |
|-----------------------|---|--|-----|-----|------|------|
| $t_{PLH}$ , $t_{PHL}$ | Propagation delay time  | See Figure 6-1   | 6   | 11  | 18.5 | ns   |
| PWD                   | Pulse width distortion <sup>(1)</sup> $ t_{PHL} - t_{PLH} $                       |  |     | 0.1 | 5.9  | ns   |
| $t_{sk(o)}$           | Channel-to-channel output skew time <sup>(2)</sup>                                | Same-direction channels                                    |     |     | 4.4  | ns   |
| $t_{sk(pp)}$          | Part-to-part skew time <sup>(3)</sup>   |  |     |     | 5    | ns   |
| $t_r$                 | Output signal rise time   | See Figure 6-1   |     | 1.3 | 3    | ns   |
| $t_f$                 | Output signal fall time   |  |     | 1.3 | 3    | ns   |
| $t_{PHZ}$             | Disable propagation delay, high-to-high impedance output                          | See Figure 6-2   |     | 17  | 31   | ns   |
| $t_{PLZ}$             | Disable propagation delay, low-to-high impedance output                           |  |     | 17  | 30   | ns   |
| $t_{PZH}$             | Enable propagation delay, high impedance-to-high output for ISO773x               |  |     | 17  | 30   | ns   |
|                       | Enable propagation delay, high impedance-to-high output for ISO773x with F suffix |  |     | 3.2 | 8.5  | μs   |
| $t_{PZL}$             | Enable propagation delay, high impedance-to-low output for ISO773x                |  |     | 3.2 | 8.5  | μs   |
|                       | Enable propagation delay, high impedance-to-low output for ISO773x with F suffix  |  |     | 17  | 30   | ns   |
| $t_{DO}$              | Default output delay time from input power loss                                   | Measured from the time VCC goes below 1.7V. See Figure 6-3 |     | 0.1 | 0.3  | μs   |
| $t_{ie}$              | Time interval error   | $2^{16} - 1$ PRBS data at 100 Mbps                         |     | 0.6 |      | ns   |

(1) Also known as pulse skew.

(2)  $t_{sk(o)}$  is the skew between outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical loads.

(3)  $t_{sk(pp)}$  is the magnitude of the difference in propagation delay times between any terminals of different devices switching in the same direction while operating at identical supply voltages, temperature, input signals and loads.

## 5.17 Switching Characteristics—2.5-V Supply

$V_{CC1} = V_{CC2} = 2.5\text{ V} \pm 10\%$  (over recommended operating conditions unless otherwise noted)

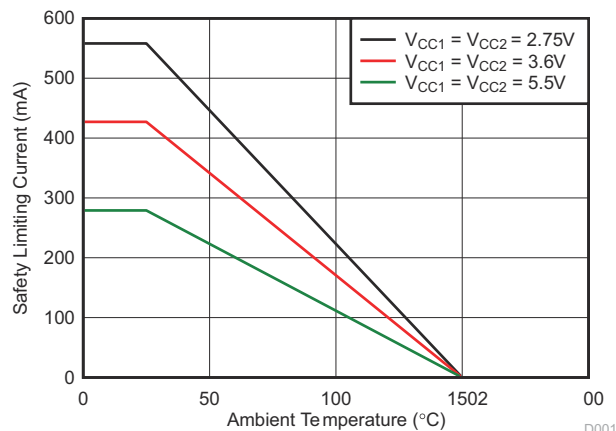
| PARAMETER             |   | TEST CONDITIONS  | MIN | TYP | MAX | UNIT |
|-----------------------|---|--|-----|-----|-----|------|
| $t_{PLH}$ , $t_{PHL}$ | Propagation delay time  | See <a href="#">Figure 6-1</a>   | 7.5 | 12  | 21  | ns   |
| PWD                   | Pulse width distortion <sup>(1)</sup> $ t_{PHL} - t_{PLH} $                       |  |     | 0.2 | 5.9 | ns   |
| $t_{sk(o)}$           | Channel-to-channel output skew time <sup>(2)</sup>                                | Same-direction channels  |     |     | 4.4 | ns   |
| $t_{sk(pp)}$          | Part-to-part skew time <sup>(3)</sup>   |  |     |     | 5.3 | ns   |
| $t_r$                 | Output signal rise time   | See <a href="#">Figure 6-1</a>   |     | 1   | 3.5 | ns   |
| $t_f$                 | Output signal fall time   |  |     | 1   | 3.5 | ns   |
| $t_{PHZ}$             | Disable propagation delay, high-to-high impedance output                          | See <a href="#">Figure 6-2</a>   |     | 22  | 41  | ns   |
| $t_{PLZ}$             | Disable propagation delay, low-to-high impedance output                           |  |     | 22  | 40  | ns   |
| $t_{PZH}$             | Enable propagation delay, high impedance-to-high output for ISO773x               |  |     | 18  | 40  | ns   |
|                       | Enable propagation delay, high impedance-to-high output for ISO773x with F suffix |  |     | 3.3 | 8.5 | μs   |
| $t_{PZL}$             | Enable propagation delay, high impedance-to-low output for ISO773x                |  |     | 3.3 | 8.5 | μs   |
|                       | Enable propagation delay, high impedance-to-low output for ISO773x with F suffix  |  |     | 18  | 40  | ns   |
| $t_{DO}$              | Default output delay time from input power loss                                   | Measured from the time VCC goes below 1.7V. See <a href="#">Figure 6-3</a> |     | 0.1 | 0.3 | μs   |
| $t_{ie}$              | Time interval error   | $2^{16} - 1$ PRBS data at 100 Mbps   |     | 0.6 |     | ns   |

(1) Also known as pulse skew.

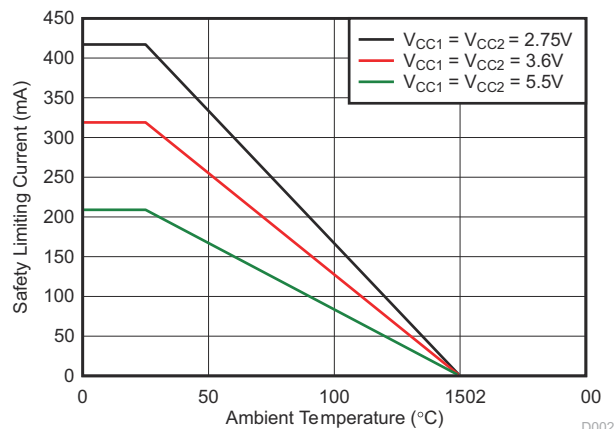
(2)  $t_{sk(o)}$  is the skew between outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical loads.

(3)  $t_{sk(pp)}$  is the magnitude of the difference in propagation delay times between any terminals of different devices switching in the same direction while operating at identical supply voltages, temperature, input signals and loads.

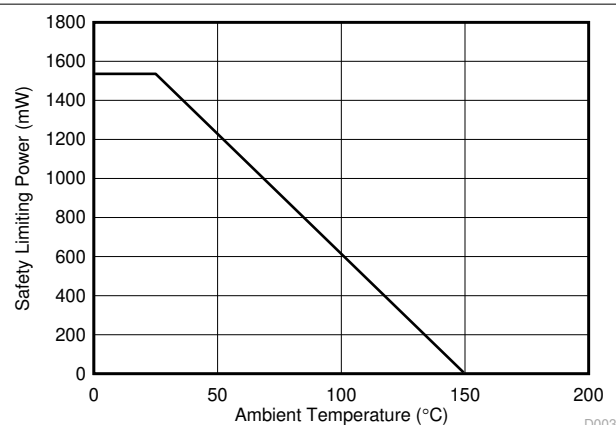
## 5.18 Insulation Characteristics Curves



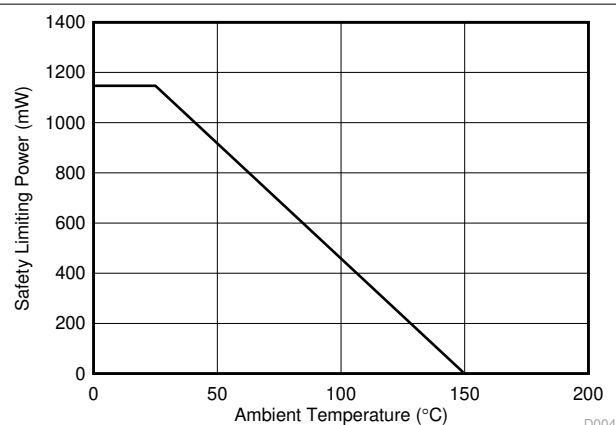
**Figure 5-1. Thermal Derating Curve for Safety Limiting Current per VDE for DW-16 Package**



**Figure 5-2. Thermal Derating Curve for Safety Limiting Current per VDE for DBQ-16 Package**

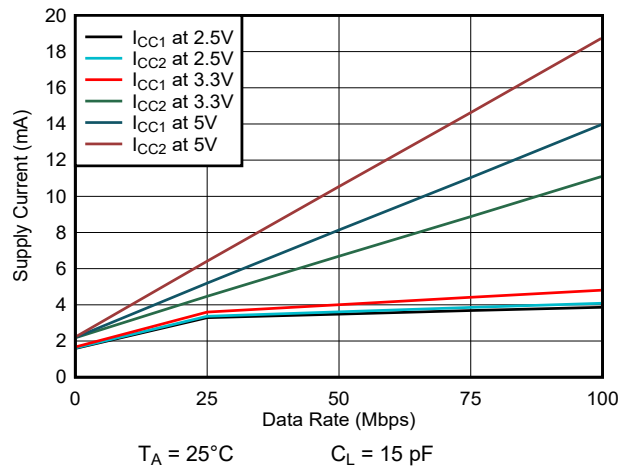


**Figure 5-3. Thermal Derating Curve for Safety Limiting Power per VDE for DW-16 Package**

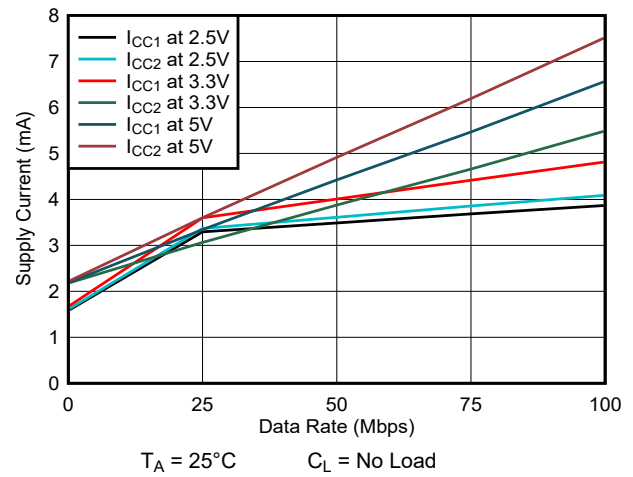


**Figure 5-4. Thermal Derating Curve for Safety Limiting Power per VDE for DBQ-16 Package**

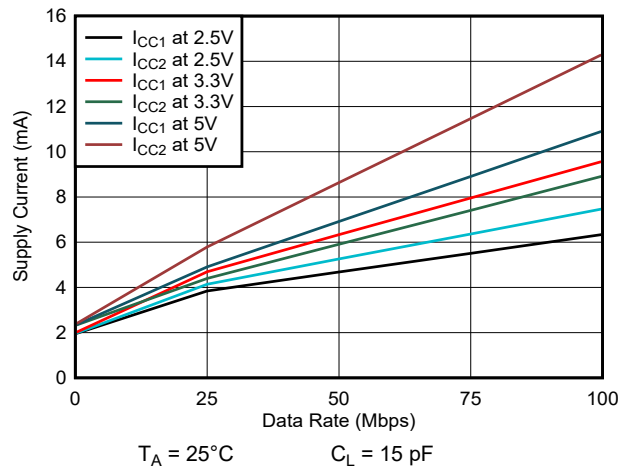
## 5.19 Typical Characteristics



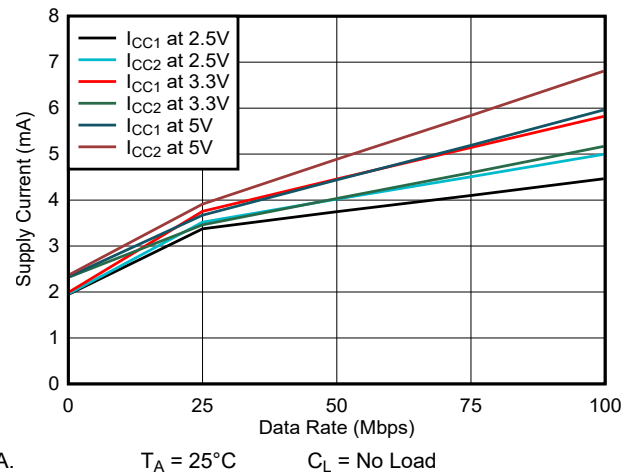
**Figure 5-5. ISO7730 Supply Current vs Data Rate (With 15-pF Load)**



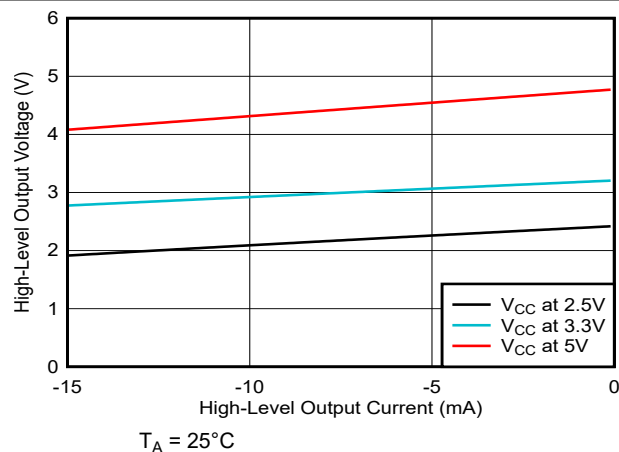
**Figure 5-6. ISO7730 Supply Current vs Data Rate (With No Load)**



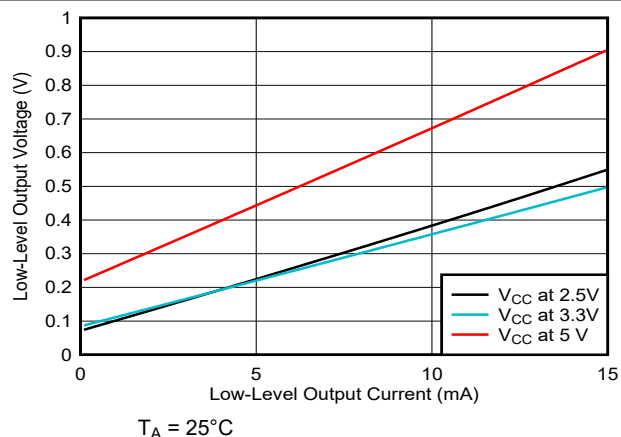
**Figure 5-7. ISO7731 Supply Current vs Data Rate (With 15-pF Load)**



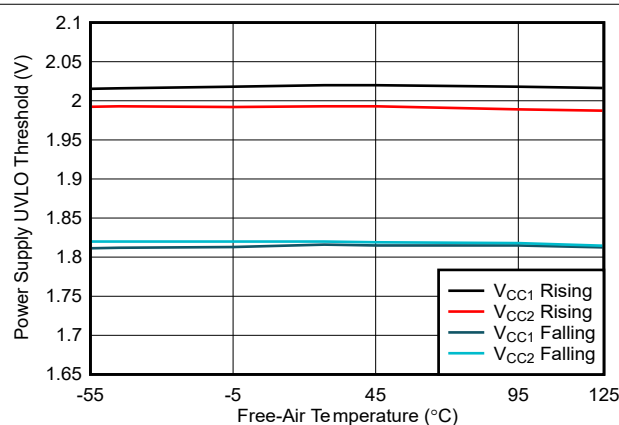
**Figure 5-8. ISO7731 Supply Current vs Data Rate (With No Load)**



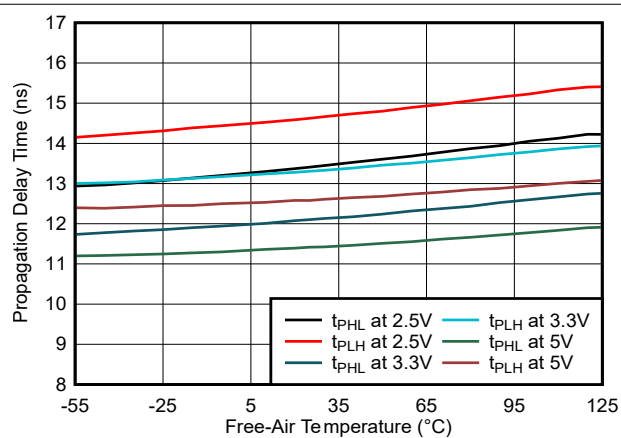
**Figure 5-9. High-Level Output Voltage vs High-level Output Current**



**Figure 5-10. Low-Level Output Voltage vs Low-Level Output Current**

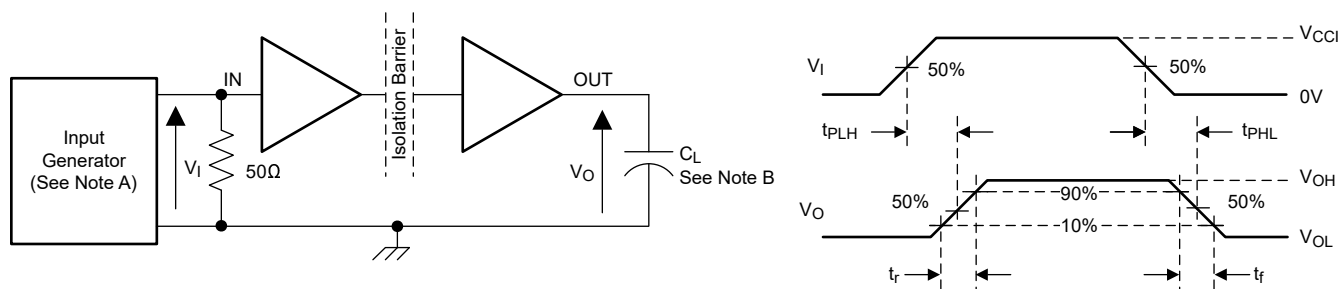


**Figure 5-11. Power Supply Undervoltage Threshold vs Free-Air Temperature**



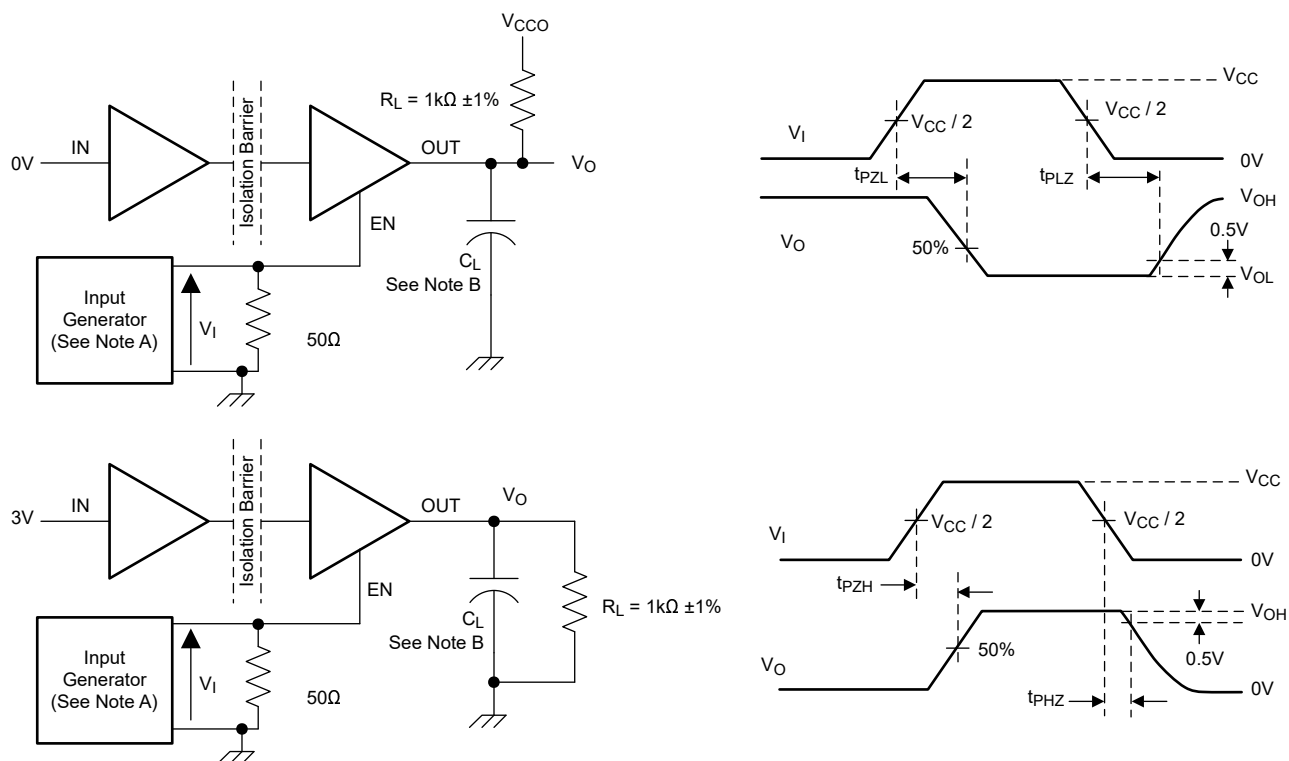
**Figure 5-12. Propagation Delay Time vs Free-Air Temperature**

## 6 Parameter Measurement Information



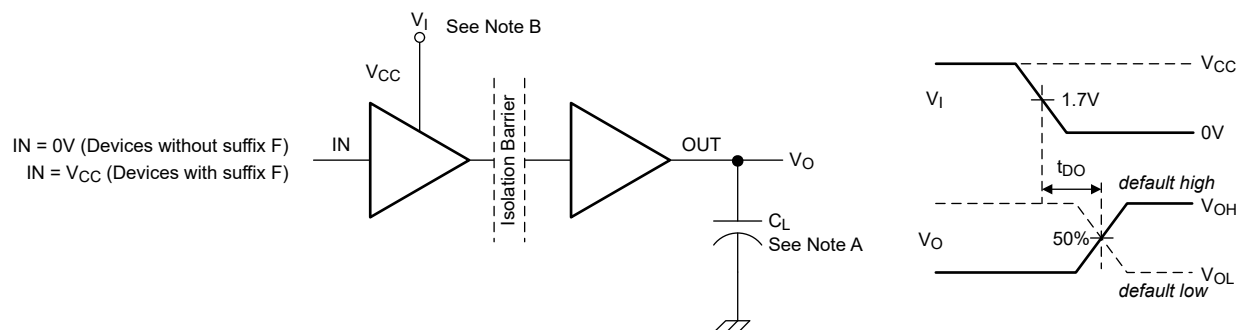
- A. The input pulse is supplied by a generator having the following characteristics:  $PRR \leq 50$  kHz, 50% duty cycle,  $t_r \leq 3$  ns,  $t_f \leq 3$  ns,  $Z_O = 50 \Omega$ . At the input,  $50 \Omega$  resistor is required to terminate Input Generator signal. The  $50 \Omega$  resistor is not needed in actual application.
- B.  $C_L = 15$  pF and includes instrumentation and fixture capacitance within  $\pm 20\%$ .

**Figure 6-1. Switching Characteristics Test Circuit and Voltage Waveforms**



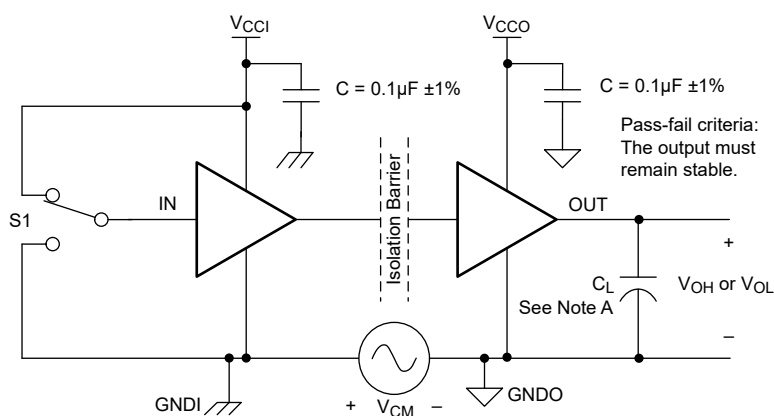
- A. The input pulse is supplied by a generator having the following characteristics:  $PRR \leq 10$  kHz, 50% duty cycle,  $t_r \leq 3$  ns,  $t_f \leq 3$  ns,  $Z_O = 50 \Omega$ .
- B.  $C_L = 15$  pF and includes instrumentation and fixture capacitance within  $\pm 20\%$ .

**Figure 6-2. Enable/Disable Propagation Delay Time Test Circuit and Waveform**



- A.  $C_L = 15$  pF and includes instrumentation and fixture capacitance within  $\pm 20\%$ .  
B. Power Supply Ramp Rate = 10 mV/ns

### Figure 6-3. Default Output Delay Time Test Circuit and Voltage Waveforms



- A.  $C_L = 15$  pF and includes instrumentation and fixture capacitance within  $\pm 20\%$ .

### Figure 6-4. Common-Mode Transient Immunity Test Circuit

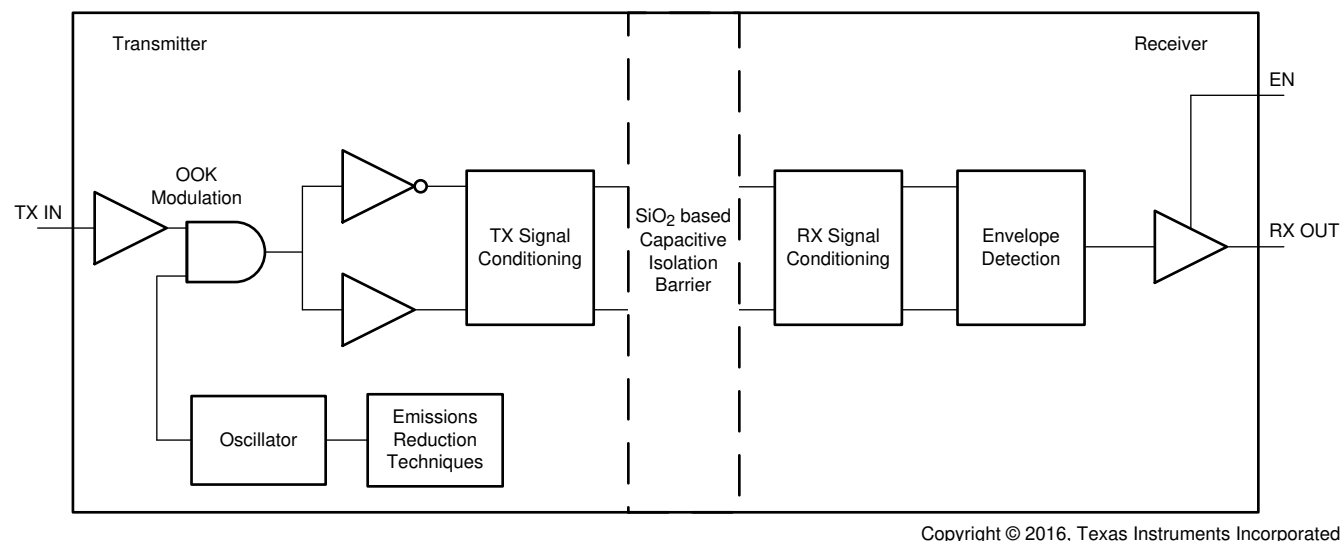


## 7 Detailed Description

### 7.1 Overview

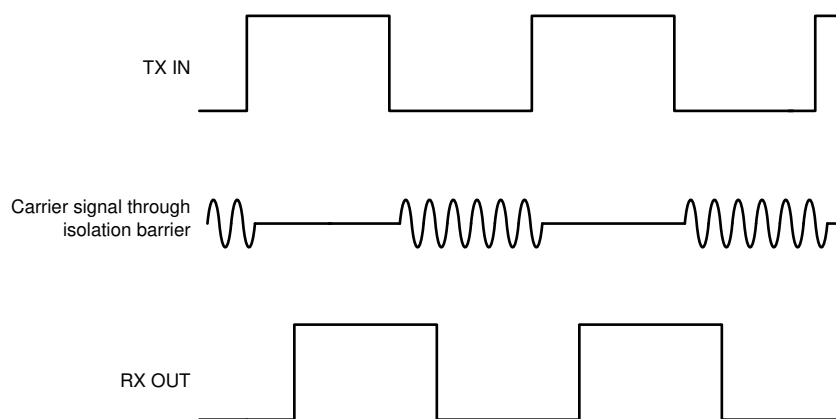
The ISO773x family of devices has an ON-OFF keying (OOK) modulation scheme to transmit the digital data across a silicon dioxide based isolation barrier. The transmitter sends a high frequency carrier across the barrier to represent one digital state and sends no signal to represent the other digital state. The receiver demodulates the signal after advanced signal conditioning and produces the output through a buffer stage. If the ENx pin is low then the output goes to high impedance. The ISO773x family of devices also incorporates advanced circuit techniques to maximize the CMTI performance and minimize the radiated emissions due the high frequency carrier and IO buffer switching. The conceptual block diagram of a digital capacitive isolator, [Figure 7-1](#), shows a functional block diagram of a typical channel.

### 7.2 Functional Block Diagram



**Figure 7-1. Conceptual Block Diagram of a Digital Capacitive Isolator**

[Figure 7-2](#) shows a conceptual detail of how the ON-OFF keying scheme works.



**Figure 7-2. On-Off Keying (OOK) Based Modulation Scheme**

## 7.3 Feature Description

Table 7-1 provides an overview of the device features.

**Table 7-1. Device Features**

| PART NUMBER            | CHANNEL DIRECTION       | MAXIMUM DATA RATE | DEFAULT OUTPUT | PACKAGE | RATED ISOLATION <sup>(1)</sup>               |
|------------------------|-------------------------|-------------------|----------------|---------|--|
| ISO7730                | 3 Forward,<br>0 Reverse | 100 Mbps          | High           | DW-16   | 5000 V <sub>RMS</sub> / 8000 V <sub>PK</sub> |
|                        |                         |                   |                | DBQ-16  | 3000 V <sub>RMS</sub> / 4242 V <sub>PK</sub> |
| ISO7730 with F suffix  | 3 Forward,<br>0 Reverse | 100 Mbps          | Low            | DW-16   | 5000 V <sub>RMS</sub> / 8000 V <sub>PK</sub> |
|                        |                         |                   |                | DBQ-16  | 3000 V <sub>RMS</sub> / 4242 V <sub>PK</sub> |
| ISO7731                | 2 Forward,<br>1 Reverse | 100 Mbps          | High           | DW-16   | 5000 V <sub>RMS</sub> / 8000 V <sub>PK</sub> |
|                        |                         |                   |                | DBQ-16  | 3000 V <sub>RMS</sub> / 4242 V <sub>PK</sub> |
| ISO7731 with F suffix  | 2 Forward,<br>1 Reverse | 100 Mbps          | Low            | DW-16   | 5000 V <sub>RMS</sub> / 8000 V <sub>PK</sub> |
|                        |                         |                   |                | DBQ-16  | 3000 V <sub>RMS</sub> / 4242 V <sub>PK</sub> |
| ISO7731B               | 2 Forward,<br>1 Reverse | 100 Mbps          | High           | DW-16   | 5000 V <sub>RMS</sub> / 8000 V <sub>PK</sub> |
| ISO7731B with F suffix | 2 Forward,<br>1 Reverse | 100 Mbps          | Low            | DW-16   | 5000 V <sub>RMS</sub> / 8000 V <sub>PK</sub> |

(1) See [Section 5.7](#) for detailed isolation ratings.

### 7.3.1 Electromagnetic Compatibility (EMC) Considerations

Many applications in harsh industrial environment are sensitive to disturbances such as electrostatic discharge (ESD), electrical fast transient (EFT), surge and electromagnetic emissions. These electromagnetic disturbances are regulated by international standards such as IEC 61000-4-x and CISPR 22. Although system-level performance and reliability depends, to a large extent, on the application board design and layout, the ISO773x family of devices incorporates many chip-level design improvements for overall system robustness. Some of these improvements include:

- Robust ESD protection cells for input and output signal pins and inter-chip bond pads.
- Low-resistance connectivity of ESD cells to supply and ground pins.
- Enhanced performance of high voltage isolation capacitor for better tolerance of ESD, EFT and surge events.
- Bigger on-chip decoupling capacitors to bypass undesirable high energy signals through a low impedance path.
- PMOS and NMOS devices isolated from each other by using guard rings to avoid triggering of parasitic SCRs.
- Reduced common mode currents across the isolation barrier by providing purely differential internal operation.

## 7.4 Device Functional Modes

Table 7-2 lists the functional modes for the ISO773x devices.

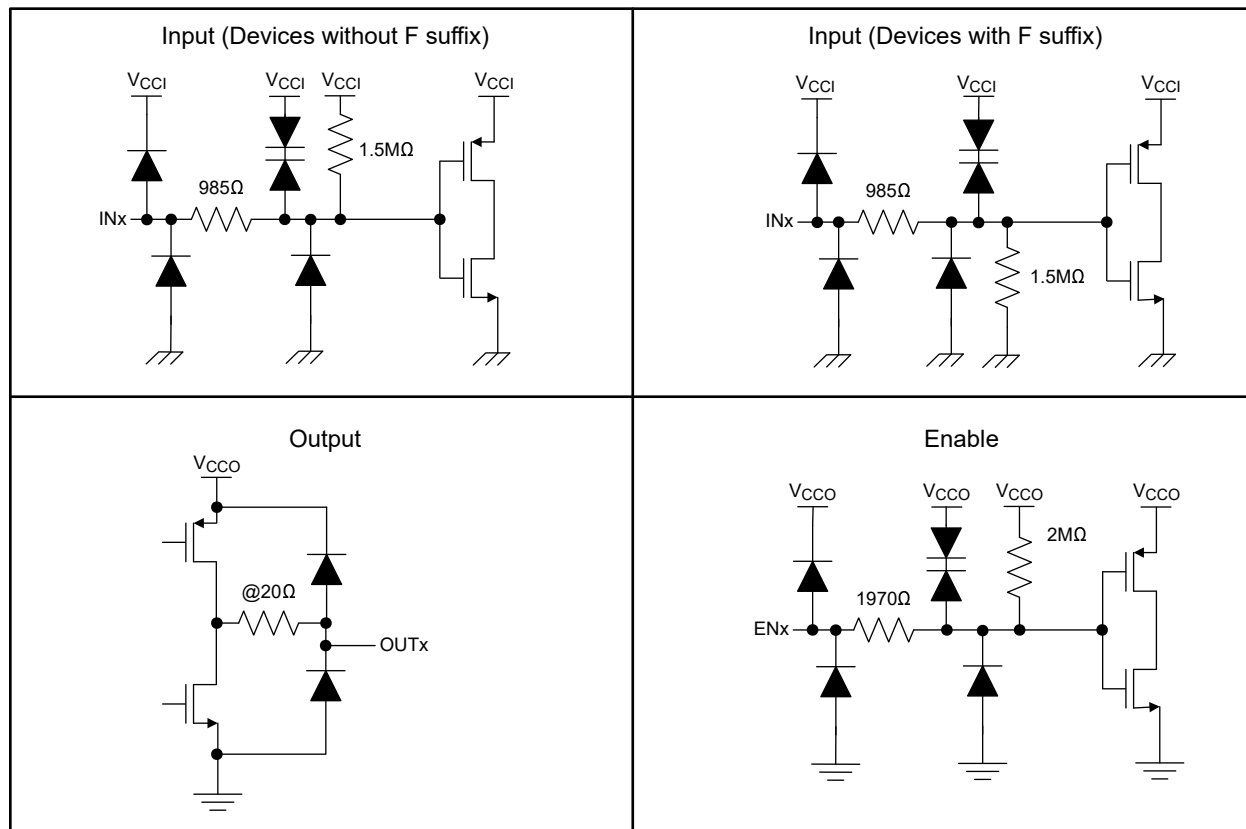
**Table 7-2. Function Table**

| V <sub>CCI</sub> | V <sub>CCO</sub> | INPUT (IN <sub>x</sub> ) <sup>(2)</sup> | OUTPUT ENABLE (EN <sub>x</sub> ) | OUTPUT (OUT <sub>x</sub> ) | COMMENTS  |
|------------------|------------------|---|----------------------------------|----------------------------|---|
| PU               | PU               | H                                       | H or open                        | H                          | Normal Operation:<br>A channel output assumes the logic state of the input.   |
|                  |                  | L                                       | H or open                        | L                          |   |
|                  |                  | Open                                    | H or open                        | Default                    | Default mode: When IN <sub>x</sub> is open, the corresponding channel output goes to the default logic state. Default is <i>High</i> for ISO773x and <i>Low</i> for ISO773x with F suffix.  |
| X                | PU               | X                                       | L                                | Z                          | A low value of Output Enable causes the outputs to be high-impedance  |
| PD               | PU               | X                                       | H or open                        | Default                    | Default mode: When V <sub>CCI</sub> is unpowered, a channel output assumes the logic state based on the selected default option. Default is <i>High</i> for ISO773x and <i>Low</i> for ISO773x with F suffix.<br>When V <sub>CCI</sub> transitions from unpowered to powered-up, a channel output assumes the logic state of the input.<br>When V <sub>CCI</sub> transitions from powered-up to unpowered, channel output assumes the selected default state. |
| X                | PD               | X                                       | X                                | Undetermined               | When V <sub>CCO</sub> is unpowered, a channel output is undetermined <sup>(1)</sup> .<br>When V <sub>CCO</sub> transitions from unpowered to powered-up, a channel output assumes the logic state of the input  |

(1) The outputs are in undetermined state when  $1.7\text{ V} < V_{CCI}$ ,  $V_{CCO} < 2.25\text{ V}$ .

(2) A strongly driven input signal can weakly power the floating V<sub>CC</sub> using an internal protection diode and cause undetermined output.

### 7.4.1 Device I/O Schematics



**Figure 7-3. Device I/O Schematics**

## 8 Application and Implementation

### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 8.1 Application Information

The ISO773x devices are high-performance, triple-channel digital isolators. These devices come with enable pins on each side which can be used to put the respective outputs in high impedance for multi-controller driving applications and reduce power consumption. The ISO773x family of devices use single-ended CMOS-logic switching technology. The voltage range is from 2.25 V to 5.5 V for both supplies,  $V_{CC1}$  and  $V_{CC2}$ . When designing with digital isolators, keep in mind that because of the single-ended design structure, digital isolators do not conform to any specific interface standard and are only intended for isolating single-ended CMOS or TTL digital signal lines. The isolator is typically placed between the data controller (that is,  $\mu C$  or UART), and a data converter or a line transceiver, regardless of the interface type or standard.

### 8.2 Typical Application

The ISO7731 device, combined with Texas Instruments' mixed-signal microcontroller, RS-485 transceiver, transformer driver, and voltage regulator, can create an isolated RS-485 system as shown in [Figure 8-1](#).

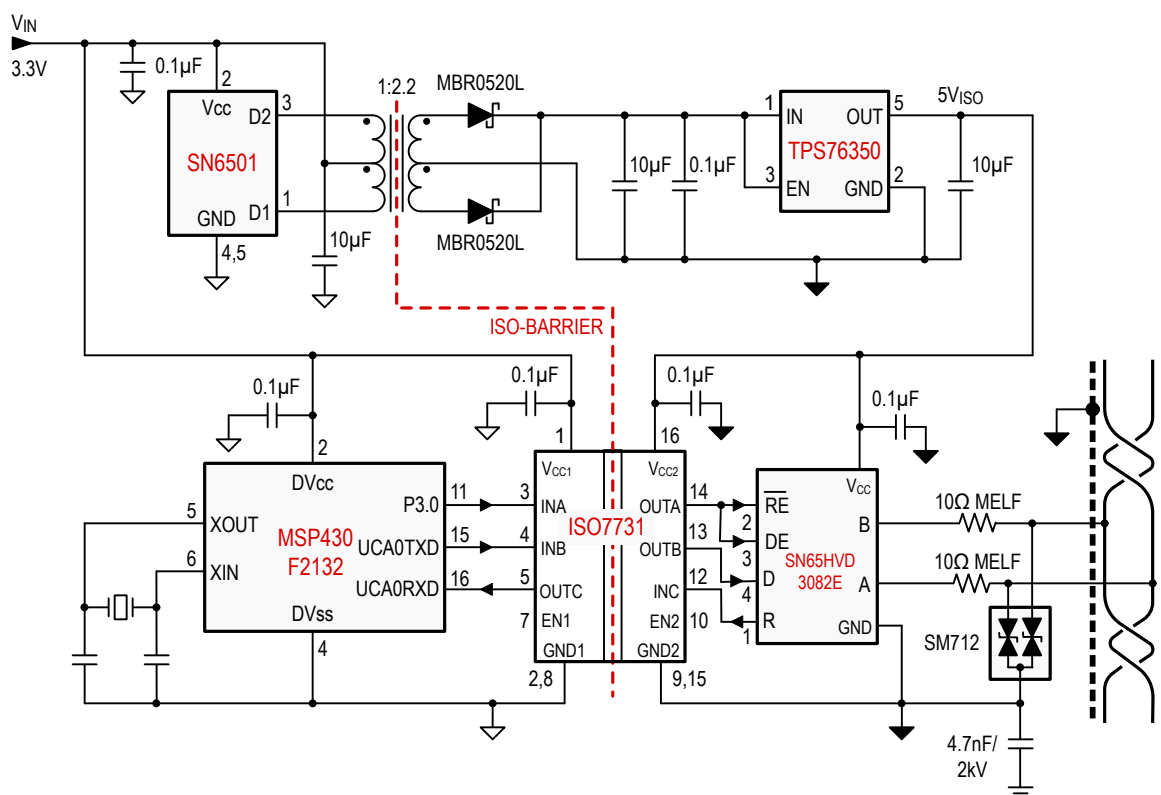


Figure 8-1. Isolated RS-485 Interface Circuit

### 8.2.1 Design Requirements

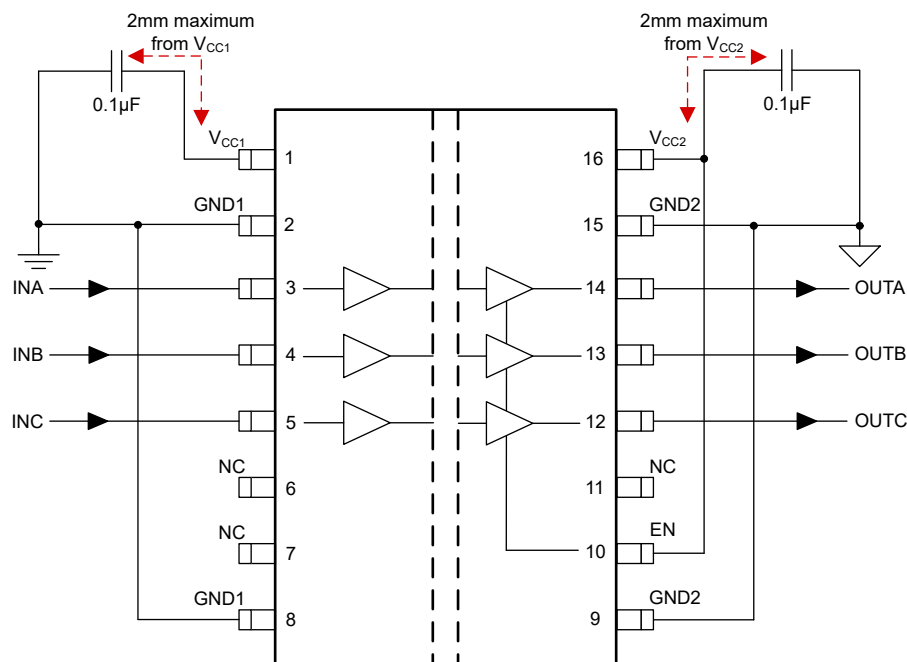
To design with these devices, use the parameters listed in [Table 8-1](#).

**Table 8-1. Design Parameters**

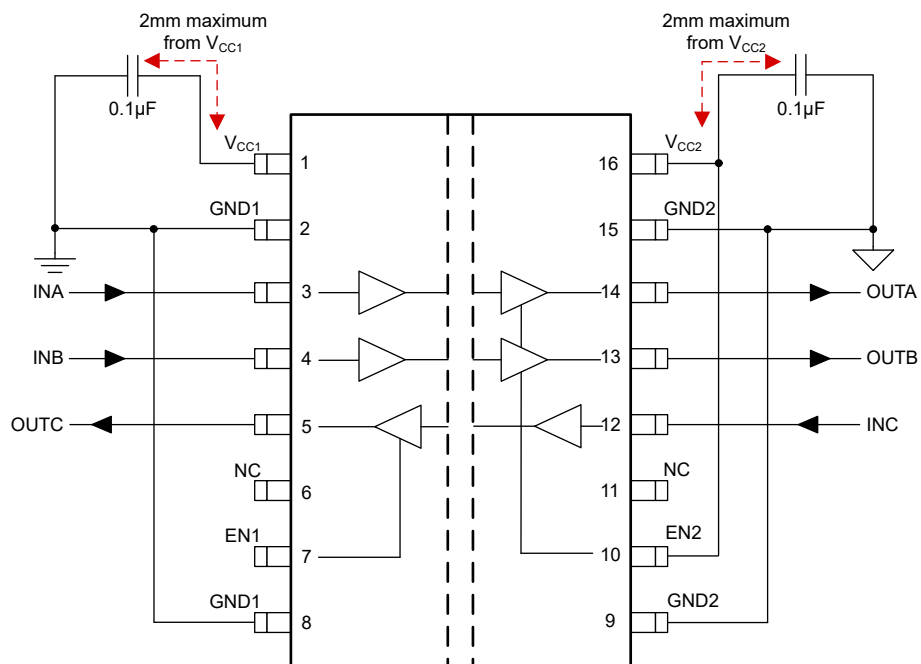
| PARAMETER                                       | VALUE         |
|---|---------------|
| Supply voltage, $V_{CC1}$ and $V_{CC2}$         | 2.25 to 5.5 V |
| Decoupling capacitor between $V_{CC1}$ and GND1 | 0.1 $\mu$ F   |
| Decoupling capacitor from $V_{CC2}$ and GND2    | 0.1 $\mu$ F   |

### 8.2.2 Detailed Design Procedure

Unlike optocouplers, which require external components to improve performance, provide bias, or limit current, the ISO773x family of devices only requires two external bypass capacitors to operate. [Figure 8-2](#) and [Figure 8-3](#) show the typical circuit hook-up for the devices.



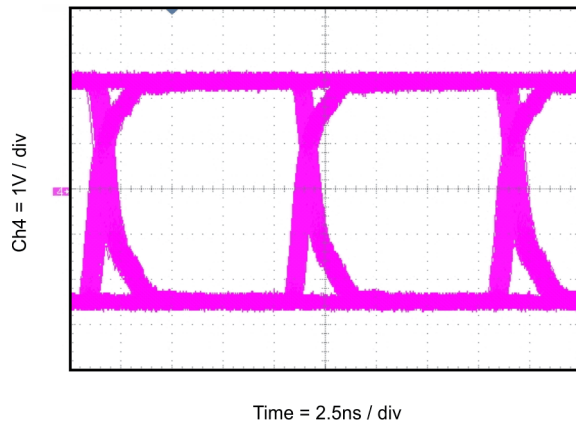
**Figure 8-2. Typical ISO7730 Circuit Hook-Up**



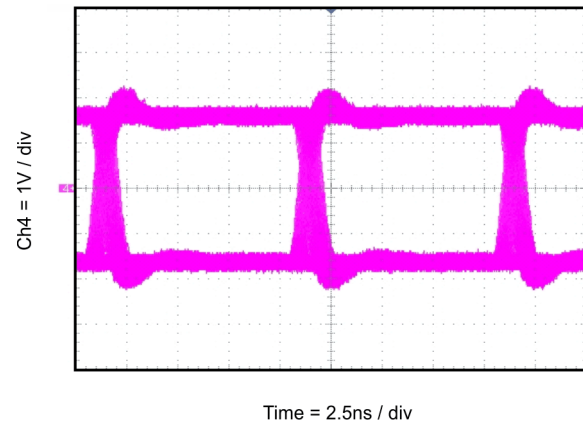
**Figure 8-3. Typical ISO7731 Circuit Hook-Up**

### 8.2.3 Application Curves

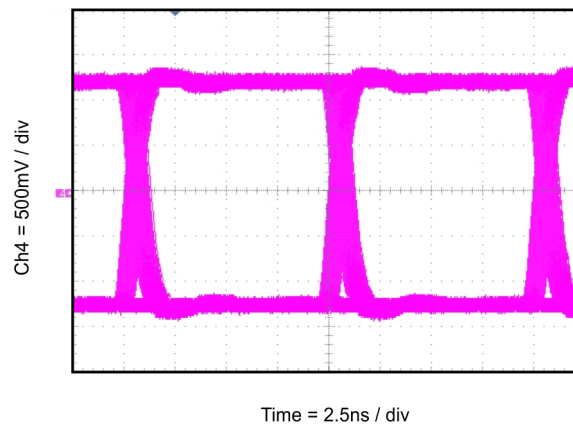
The following typical eye diagrams of the ISO773x family of devices indicate low jitter and wide open eye at the maximum data rate of 100 Mbps.



**Figure 8-4. Eye Diagram at 100 Mbps PRBS  $2^{16} - 1$ , 5 V and 25°C**



**Figure 8-5. Eye Diagram at 100 Mbps PRBS  $2^{16} - 1$ , 3.3 V and 25°C**



**Figure 8-6. Eye Diagram at 100 Mbps PRBS  $2^{16} - 1$ , 2.5 V and 25°C**

#### 8.2.3.1 Insulation Lifetime

Insulation lifetime projection data is collected by using industry-standard Time Dependent Dielectric Breakdown (TDDB) test method. In this test, all pins on each side of the barrier are tied together creating a two-terminal device and high voltage applied between the two sides; See [Figure 8-7](#) for TDDB test setup. The insulation breakdown data is collected at various high voltages switching at 60 Hz over temperature. For reinforced insulation, VDE standard requires the use of TDDB projection line with failure rate of less than 1 part per million (ppm). Even though the expected minimum insulation lifetime is 20 years at the specified working isolation voltage, VDE reinforced certification requires additional safety margin of 20% for working voltage and 50% for lifetime which translates into minimum required insulation lifetime of 30 years at a working voltage that is 20% higher than the specified value.

[Figure 8-8](#) shows the intrinsic capability of the isolation barrier to withstand high voltage stress over the lifetime of the barrier. Based on the TDDB data, the intrinsic capability of the insulation is 1500 V<sub>RMS</sub> with a lifetime of 36 years. Other factors, such as package size, pollution degree, material group, and more can further limit the working voltage of the component. The working voltage of DW-16 package is specified up to 1500 V<sub>RMS</sub>. At the lower working voltages, the corresponding insulation lifetime is much longer than 36 years. DBQ-16 package at 400 V<sub>RMS</sub> working voltage has a much longer lifetime than DW-16 package.

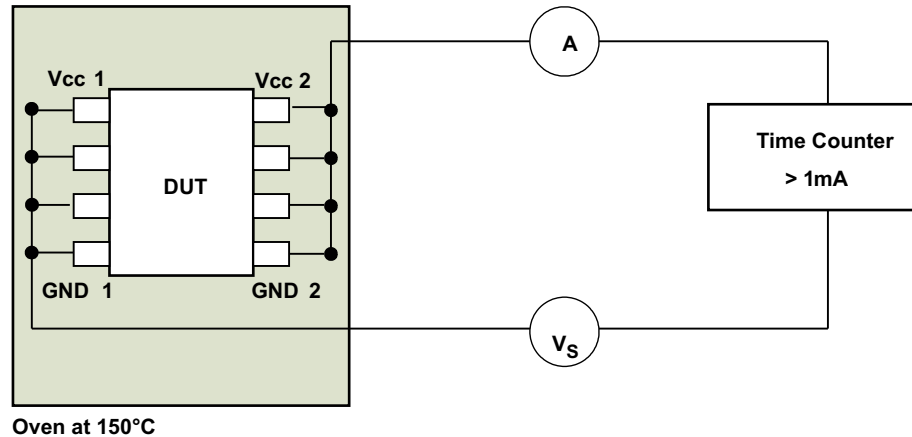


Figure 8-7. Test Setup for Insulation Lifetime Measurement

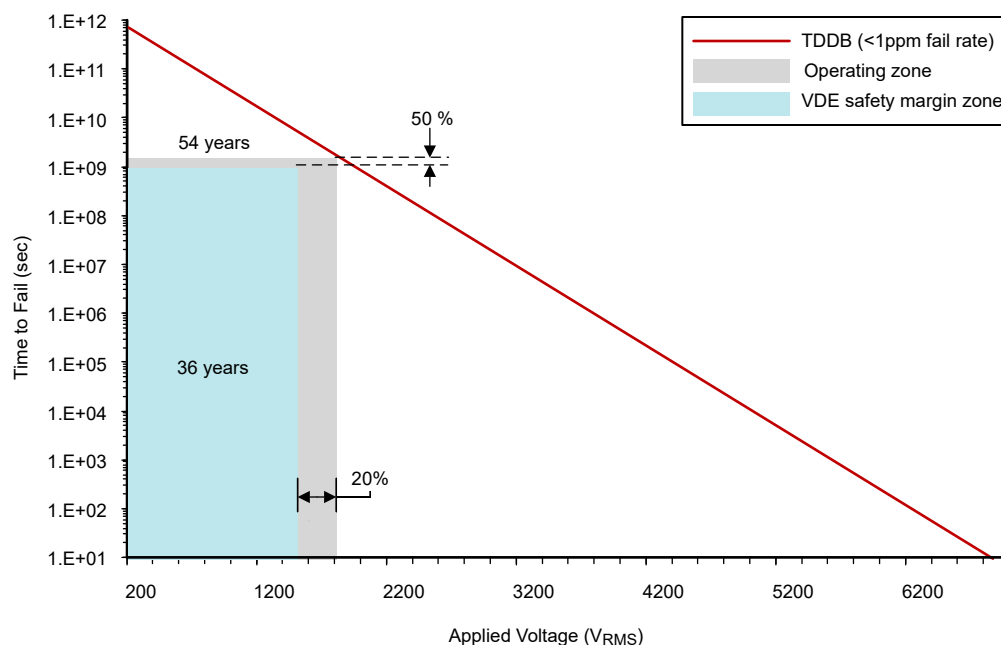


Figure 8-8. Insulation Lifetime Projection Data

### 8.3 Power Supply Recommendations

To help provide reliable operation at data rates and supply voltages, a 0.1- $\mu$ F bypass capacitor is recommended at the input and output supply pins ( $V_{CC1}$  and  $V_{CC2}$ ). The capacitors must be placed as close to the supply pins as possible. If only a single primary-side power supply is available in an application, isolated power can be generated for the secondary-side with the help of a transformer driver such as Texas Instruments' [SN6501](#) or [SN6505A](#). For such applications, detailed power supply design and transformer selection recommendations are available in the [SN6501 Transformer Driver for Isolated Power Supplies data sheet](#) or [SN6505A Low-Noise 1-A Transformer Drivers for Isolated Power Supplies](#) (SLLSEP9).

### 8.4 Layout

#### 8.4.1 Layout Guidelines

A minimum of four layers is required to accomplish a low EMI PCB design (see [Figure 8-9](#)). Layer stacking must be in the following order (top-to-bottom): high-speed signal layer, ground plane, power plane and low-frequency signal layer.



- Routing the high-speed traces on the top layer avoids the use of vias (and the introduction of the inductances) and allows for clean interconnects between the isolator and the transmitter and receiver circuits of the data link.
- Placing a solid ground plane next to the high-speed signal layer establishes controlled impedance for transmission line interconnects and provides an excellent low-inductance path for the return current flow.
- Placing the power plane next to the ground plane creates additional high-frequency bypass capacitance of approximately 100 pF/inch<sup>2</sup>.
- Routing the slower speed control signals on the bottom layer allows for greater flexibility as these signal links typically have margin to tolerate discontinuities such as vias.

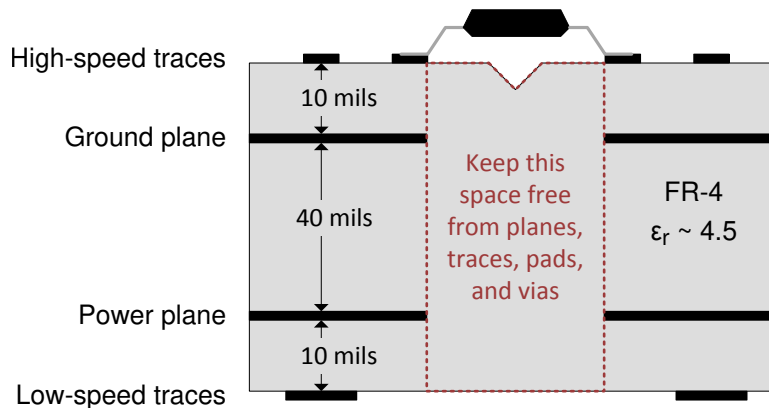
If an additional supply voltage plane or signal layer is needed, add a second power or ground plane system to the stack to keep the planes symmetrical. This makes the stack mechanically stable and prevents warping. Also the power and ground plane of each power system can be placed closer together, thus increasing the high-frequency bypass capacitance significantly.

For detailed layout recommendations, refer to the [Digital Isolator Design Guide](#).

#### 8.4.1.1 PCB Material

For digital circuit boards operating below 150 Mbps, (or rise and fall times higher than 1 ns), and trace lengths of up to 10 inches, use standard FR-4 UL94V-0 printed circuit boards. This PCB is preferred over cheaper alternatives due to its lower dielectric losses at high frequencies, less moisture absorption, greater strength and stiffness, and self-extinguishing flammability-characteristics.

#### 8.4.2 Layout Example



**Figure 8-9. Layout Example Schematic**

## 9 Device and Documentation Support

### 9.1 Documentation Support

#### 9.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, [Digital Isolator Design Guide](#)
- Texas Instruments, [Isolation Glossary](#)
- Texas Instruments, [How to use isolation to improve ESD, EFT, and Surge immunity in industrial systems application report](#)
- Texas Instruments, [SN6501 Transformer Driver for Isolated Power Supplies data sheet](#)
- Texas Instruments, [SNx5HVD308xE Low-Power RS-485 Transceivers, Available in a Small MSOP-8 Package data sheet](#)
- Texas Instruments, [TPS76350 Low-Power 150-mA Low-Dropout Linear Regulators data sheet](#)
- Texas Instruments, [MSP430F2132 Mixed Signal Microcontroller data sheet](#)

### 9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 9.3 Support Resources

**TI E2E™ support forums** are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

### 9.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

### 9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 9.6 Glossary

**TI Glossary** This glossary lists and explains terms, acronyms, and definitions.

## 10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| Changes from Revision J (October 2024) to Revision K (September 2025)   | Page |
|---|------|
| • Added Low-level input current for INx and High-level Input current for ENx throughout the <i>Specifications</i> ..... | 4    |

| Changes from Revision I (August 2023) to Revision J (October 2024)                                       | Page |
|--|------|
| • Updated the numbering format for tables, figures, and cross-references throughout the document.....    | 1    |
| • Updated distance through isolation, while maintaining other insulation specifications.....             | 7    |
| • Updated the input leakage current for ENx pins throughout the electrical characteristic sections ..... | 11   |

|  |    |
|--|----|
| • Updated the TDDDB plot and the projected lifetime.....   | 31 |
| • Deleted the <i>Community Resources</i> section and added the <i>Support Resources</i> section..... | 34 |

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|   |             |
|---|-------------|
| <b>Changes from Revision H (March 2023) to Revision I (August 2023)</b> | <b>Page</b> |
|---|-------------|

|  |    |
|--|----|
| • Updated Thermal Characteristics, Safety Limiting Values, and Thermal Derating Curves to provide more accurate system-level thermal calculations..... | 10 |
| • Updated electrical and switching characteristics to match device performance.....  | 17 |

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|  |             |
|--|-------------|
| <b>Changes from Revision G (March 2020) to Revision H (March 2023)</b> | <b>Page</b> |
|--|-------------|

|   |   |
|---|---|
| • Changed standard name from: "DIN V VDE V 0884-11:2017-01" to: "DIN EN IEC 60747-17 (VDE 0884-17)" throughout the document.....                | 1 |
| • Removed references to standard IEC/EN/CSA 60950-1 throughout the document .....   | 1 |
| • Removed standard revision and year references from all standard names throughout the document.....  | 1 |
| • Added Maximum impulse voltage ( $V_{IMP}$ ) specification per DIN EN IEC 60747-17 (VDE 0884-17).....  | 7 |
| • Changed test conditions and values of Maximum surge isolation voltage ( $V_{IOSM}$ ) specification per DIN EN IEC 60747-17 (VDE 0884-17)..... | 7 |
| • Clarified method b test conditions of Apparent charge ( $q_{PD}$ ).....   | 7 |
| • Changed values of Maximum surge isolation voltage ( $V_{IOSM}$ ) specification per DIN EN IEC 60747-17 (VDE 0884-17).....                     | 9 |

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## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

| Orderable part number        | Status<br>(1) | Material type<br>(2) | Package   Pins  | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|------------------------------|---------------|----------------------|-----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">ISO7730DBQR</a>  | Active        | Production           | SSOP (DBQ)   16 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | 7730                |
| ISO7730DBQR.A                | Active        | Production           | SSOP (DBQ)   16 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | 7730                |
| ISO7730DBQR.B                | Active        | Production           | SSOP (DBQ)   16 | 2500   LARGE T&R      | -           | Call TI                              | Call TI                           | -55 to 125   |                     |
| <a href="#">ISO7730DWR</a>   | Active        | Production           | SOIC (DW)   16  | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7730             |
| ISO7730DWR.A                 | Active        | Production           | SOIC (DW)   16  | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7730             |
| ISO7730DWR.B                 | Active        | Production           | SOIC (DW)   16  | 2000   LARGE T&R      | -           | Call TI                              | Call TI                           | -55 to 125   |                     |
| <a href="#">ISO7730FDBQR</a> | Active        | Production           | SSOP (DBQ)   16 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | 7730F               |
| ISO7730FDBQR.A               | Active        | Production           | SSOP (DBQ)   16 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | 7730F               |
| ISO7730FDBQR.B               | Active        | Production           | SSOP (DBQ)   16 | 2500   LARGE T&R      | -           | Call TI                              | Call TI                           | -55 to 125   |                     |
| <a href="#">ISO7730FDWR</a>  | Active        | Production           | SOIC (DW)   16  | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7730F            |
| ISO7730FDWR.A                | Active        | Production           | SOIC (DW)   16  | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7730F            |
| ISO7730FDWR.B                | Active        | Production           | SOIC (DW)   16  | 2000   LARGE T&R      | -           | Call TI                              | Call TI                           | -55 to 125   |                     |
| <a href="#">ISO7731BDWR</a>  | Active        | Production           | SOIC (DW)   16  | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7731B            |
| ISO7731BDWR.A                | Active        | Production           | SOIC (DW)   16  | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7731B            |
| ISO7731BDWR.B                | Active        | Production           | SOIC (DW)   16  | 2000   LARGE T&R      | -           | Call TI                              | Call TI                           | -55 to 125   |                     |
| <a href="#">ISO7731DBQR</a>  | Active        | Production           | SSOP (DBQ)   16 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | 7731                |
| ISO7731DBQR.A                | Active        | Production           | SSOP (DBQ)   16 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | 7731                |
| ISO7731DBQR.B                | Active        | Production           | SSOP (DBQ)   16 | 2500   LARGE T&R      | -           | Call TI                              | Call TI                           | -55 to 125   |                     |
| ISO7731DBQRG4                | Active        | Production           | SSOP (DBQ)   16 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | 7731                |
| ISO7731DBQRG4.A              | Active        | Production           | SSOP (DBQ)   16 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | 7731                |
| ISO7731DBQRG4.B              | Active        | Production           | SSOP (DBQ)   16 | 2500   LARGE T&R      | -           | Call TI                              | Call TI                           | -55 to 125   |                     |
| <a href="#">ISO7731DWR</a>   | Active        | Production           | SOIC (DW)   16  | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7731             |
| ISO7731DWR.A                 | Active        | Production           | SOIC (DW)   16  | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7731             |
| ISO7731DWR.B                 | Active        | Production           | SOIC (DW)   16  | 2000   LARGE T&R      | -           | Call TI                              | Call TI                           | -55 to 125   |                     |
| <a href="#">ISO7731FBDWR</a> | Active        | Production           | SOIC (DW)   16  | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7731FB           |
| ISO7731FBDWR.A               | Active        | Production           | SOIC (DW)   16  | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7731FB           |
| ISO7731FBDWR.B               | Active        | Production           | SOIC (DW)   16  | 2000   LARGE T&R      | -           | Call TI                              | Call TI                           | -55 to 125   |                     |
| <a href="#">ISO7731FDBQR</a> | Active        | Production           | SSOP (DBQ)   16 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | 7731F               |
| ISO7731FDBQR.A               | Active        | Production           | SSOP (DBQ)   16 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | 7731F               |

| Orderable part number       | Status<br>(1) | Material type<br>(2) | Package   Pins  | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|-----------------------------|---------------|----------------------|-----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| ISO7731FDBQR.B              | Active        | Production           | SSOP (DBQ)   16 | 2500   LARGE T&R      | -           | Call TI                              | Call TI                           | -55 to 125   |                     |
| <a href="#">ISO7731FDWR</a> | Active        | Production           | SOIC (DW)   16  | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7731F            |
| ISO7731FDWR.A               | Active        | Production           | SOIC (DW)   16  | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7731F            |
| ISO7731FDWR.B               | Active        | Production           | SOIC (DW)   16  | 2000   LARGE T&R      | -           | Call TI                              | Call TI                           | -55 to 125   |                     |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:**The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## OTHER QUALIFIED VERSIONS OF ISO7730, ISO7731 :

- Automotive : [ISO7730-Q1](#), [ISO7731-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

**TAPE AND REEL INFORMATION**


\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| ISO7730DBQR  | SSOP         | DBQ             | 16   | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| ISO7730DBQR  | SSOP         | DBQ             | 16   | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| ISO7730DBQR  | SSOP         | DBQ             | 16   | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| ISO7730DWR   | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| ISO7730DWR   | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| ISO7730DWR   | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| ISO7730FDBQR | SSOP         | DBQ             | 16   | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| ISO7730FDBQR | SSOP         | DBQ             | 16   | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| ISO7730FDBQR | SSOP         | DBQ             | 16   | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| ISO7730FDWR  | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| ISO7730FDWR  | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| ISO7731BDWR  | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| ISO7731BDWR  | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| ISO7731DBQR  | SSOP         | DBQ             | 16   | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| ISO7731DBQR  | SSOP         | DBQ             | 16   | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| ISO7731DBQR  | SSOP         | DBQ             | 16   | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |

| Device        | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| ISO7731DBQRG4 | SSOP         | DBQ             | 16   | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| ISO7731DBQRG4 | SSOP         | DBQ             | 16   | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| ISO7731DWR    | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| ISO7731FBDWR  | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| ISO7731FBDWR  | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| ISO7731FDBQR  | SSOP         | DBQ             | 16   | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| ISO7731FDBQR  | SSOP         | DBQ             | 16   | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| ISO7731FDBQR  | SSOP         | DBQ             | 16   | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| ISO7731FDWR   | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |



## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device        | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| ISO7730DBQR   | SSOP         | DBQ             | 16   | 2500 | 353.0       | 353.0      | 32.0        |
| ISO7730DBQR   | SSOP         | DBQ             | 16   | 2500 | 350.0       | 350.0      | 43.0        |
| ISO7730DBQR   | SSOP         | DBQ             | 16   | 2500 | 350.0       | 350.0      | 43.0        |
| ISO7730DWR    | SOIC         | DW              | 16   | 2000 | 356.0       | 356.0      | 36.0        |
| ISO7730DWR    | SOIC         | DW              | 16   | 2000 | 353.0       | 353.0      | 32.0        |
| ISO7730DWR    | SOIC         | DW              | 16   | 2000 | 356.0       | 356.0      | 45.0        |
| ISO7730FDBQR  | SSOP         | DBQ             | 16   | 2500 | 350.0       | 350.0      | 43.0        |
| ISO7730FDBQR  | SSOP         | DBQ             | 16   | 2500 | 353.0       | 353.0      | 32.0        |
| ISO7730FDBQR  | SSOP         | DBQ             | 16   | 2500 | 350.0       | 350.0      | 43.0        |
| ISO7730FDWR   | SOIC         | DW              | 16   | 2000 | 356.0       | 356.0      | 45.0        |
| ISO7730FDWR   | SOIC         | DW              | 16   | 2000 | 353.0       | 353.0      | 32.0        |
| ISO7731BDWR   | SOIC         | DW              | 16   | 2000 | 356.0       | 356.0      | 36.0        |
| ISO7731BDWR   | SOIC         | DW              | 16   | 2000 | 353.0       | 353.0      | 32.0        |
| ISO7731DBQR   | SSOP         | DBQ             | 16   | 2500 | 353.0       | 353.0      | 32.0        |
| ISO7731DBQR   | SSOP         | DBQ             | 16   | 2500 | 350.0       | 350.0      | 43.0        |
| ISO7731DBQR   | SSOP         | DBQ             | 16   | 2500 | 350.0       | 350.0      | 43.0        |
| ISO7731DBQRG4 | SSOP         | DBQ             | 16   | 2500 | 350.0       | 350.0      | 43.0        |
| ISO7731DBQRG4 | SSOP         | DBQ             | 16   | 2500 | 350.0       | 350.0      | 43.0        |

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| Device       | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| ISO7731DWR   | SOIC         | DW              | 16   | 2000 | 353.0       | 353.0      | 32.0        |
| ISO7731FBDWR | SOIC         | DW              | 16   | 2000 | 356.0       | 356.0      | 36.0        |
| ISO7731FBDWR | SOIC         | DW              | 16   | 2000 | 353.0       | 353.0      | 32.0        |
| ISO7731FDBQR | SSOP         | DBQ             | 16   | 2500 | 353.0       | 353.0      | 32.0        |
| ISO7731FDBQR | SSOP         | DBQ             | 16   | 2500 | 350.0       | 350.0      | 43.0        |
| ISO7731FDBQR | SSOP         | DBQ             | 16   | 2500 | 350.0       | 350.0      | 43.0        |
| ISO7731FDWR  | SOIC         | DW              | 16   | 2000 | 353.0       | 353.0      | 32.0        |

## GENERIC PACKAGE VIEW

**DW 16**

**SOIC - 2.65 mm max height**

7.5 x 10.3, 1.27 mm pitch

SMALL OUTLINE INTEGRATED CIRCUIT

This image is a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.



4224780/A



DW0016B

# PACKAGE OUTLINE

## SOIC - 2.65 mm max height

SOIC



4221009/B 07/2016

### NOTES:

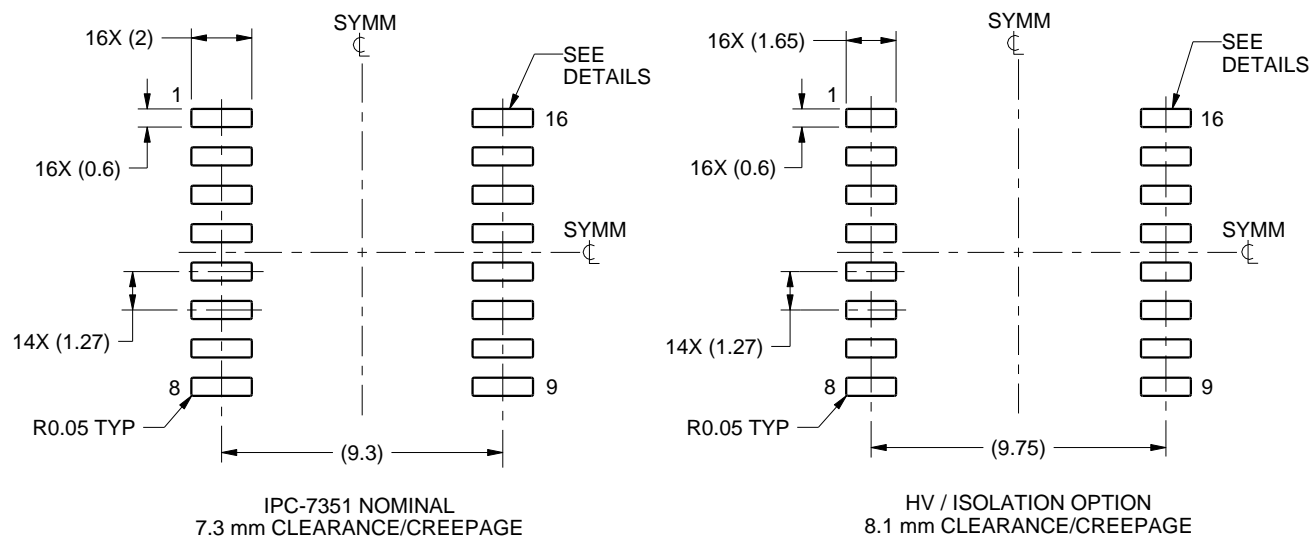
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.
5. Reference JEDEC registration MS-013.

# EXAMPLE BOARD LAYOUT

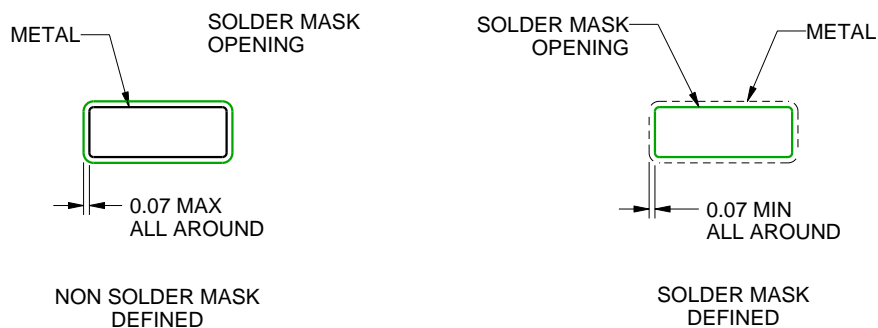
DW0016B

SOIC - 2.65 mm max height

SOIC



LAND PATTERN EXAMPLE  
SCALE:4X



SOLDER MASK DETAILS

4221009/B 07/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

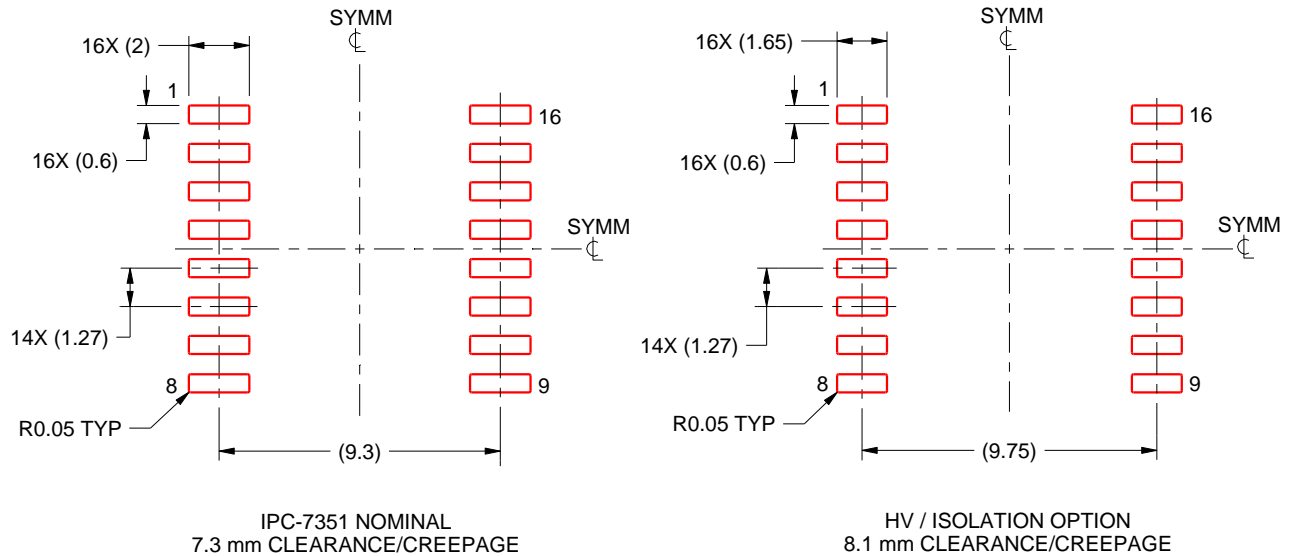
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DW0016B

SOIC - 2.65 mm max height

SOIC



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:4X

4221009/B 07/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



**DBQ0016A**

# PACKAGE OUTLINE

**SSOP - 1.75 mm max height**

SHRINK SMALL-OUTLINE PACKAGE



4214846/A 03/2014

## NOTES:

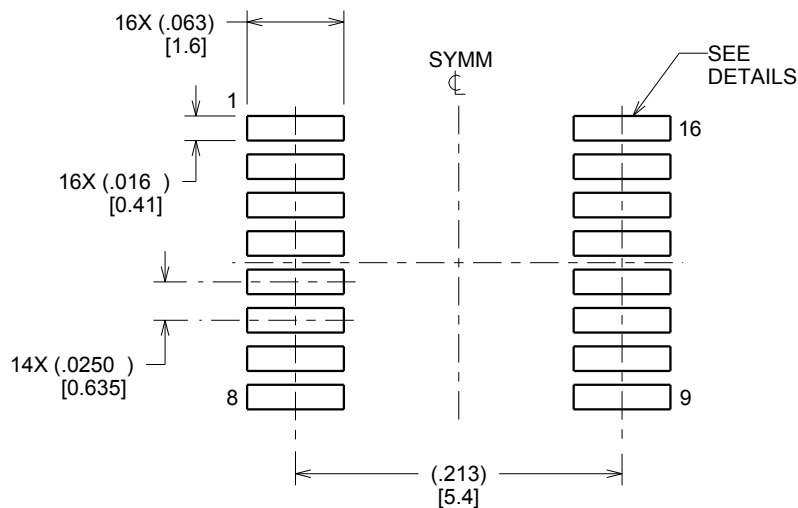
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 inch, per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MO-137, variation AB.

# EXAMPLE BOARD LAYOUT

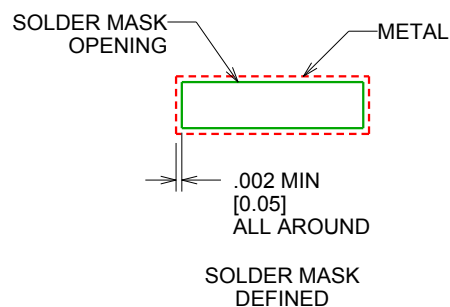
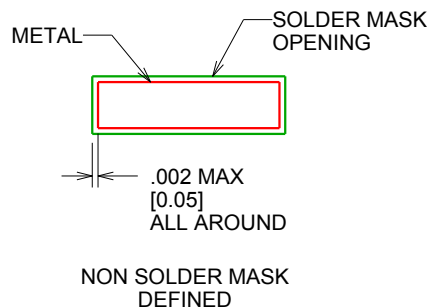
DBQ0016A

SSOP - 1.75 mm max height

SHRINK SMALL-OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
SCALE:8X



SOLDER MASK DETAILS

4214846/A 03/2014

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

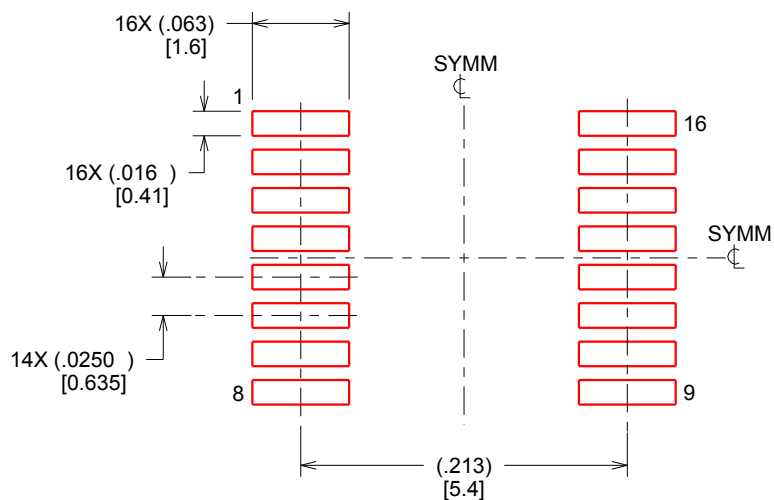


## EXAMPLE STENCIL DESIGN

DBQ0016A

SSOP - 1.75 mm max height

SHRINK SMALL-OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON .005 INCH [0.127 MM] THICK STENCIL  
SCALE:8X

4214846/A 03/2014

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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